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I

(Acts whose publication is obligatory)

COUNCIL REGULATION (EEC) No 1945/86

of 18 June 1986

temporarily suspending the autonomous Common Customs Tariff duties on a number of industrial products

THE COUNCIL OF THE EUROPEAN COMMUNITIES,

HAS ADOPTED THIS REGULATION:

Having regard to the Treaty establishing the European Economic Community, and in particular Article 28 thereof,

Article 1

Having regard to the draft Regulation submitted by the Commission,

The autonomous Common Customs Tariff duties for the products listed in the tables annexed to this Regulation shall be suspended at the level indicated in respect of each of them.

Whereas production of the products referred to in this Regulation is at present inadequate or non-existent within the Community and producers are thus unable to meet the needs of user industries in the Community;

These suspensions shall be valid:

Whereas it is in the Community's interest to suspend the autonomous Common Customs Tariff duties only partially in certain cases, due particularly to the existence of Community production, and to suspend them completely in other cases;

— from 1 July to 31 December 1986 for the products listed in Table I,

— from 1 July 1986 to 30 June 1987 for the products listed in Table II.

Whereas, taking account of the difficulties involved in accurately assessing the development of the economic situation in the sectors concerned in the near future, these suspension measures should be taken only temporarily with their term of validity fixed to coincide with the interests of Community production,

Article 2

This Regulation shall enter into force on 1 July 1986.

This Regulation shall be binding in its entirety and directly applicable in all Member States.

Done at Luxembourg, 18 June 1986.

For the Council

The President

N. SMIT-KROES

ANNEX

TABLE 1

CCT heading No	Description	Rate of autonomous duty (%)
ex 27.13 B II	Synthetic paraffin wax having a molecular weight of not less than 460 and not more than 1 560	0
ex 28.20 A	Aluminium hydroxide oxide in the form of pseudo-boehmite	4
ex 28.52 B	Lanthanum bromide oxide	0
ex 29.02 A I	Hexafluoropropene	0
ex 29.02 A III	Dibromomethane	3
ex 29.03 C I	Ethanesulphonyl chloride	3
ex 29.06 A IV	3-Ethylphenol	0
ex 29.08 A III c) and ex 34.02	Aqueous solution containing not less than 30 % and not more than 50 % of disodium alkyl [oxydi (benzenesulphonate)]	0
ex 29.09 B	1,2-Epoxybutane	0
ex 29.09 B	1,2-Epoxy-4-(epoxyethyl)cyclohexane	0
ex 29.10 B	8,9-Epoxy-3-(3,4-epoxycyclohexyl)-2,4-dioxaspiro [5,5] undecane	0
ex 29.14 B I	2,3-Epoxypropyl methacrylate	0
ex 29.16 D	3,4-Epoxycyclohexylmethyl 3,4-epoxycyclohexanecarboxylate	0
ex 29.16 D	Methyl 5-(2,4-dichlorophenoxy)-2-nitrobenzoate	3,5
ex 29.25 B II c)	Barbituric acid	0
ex 29.26 A I	1,2-Benzisothiazol-3-one 1,1-dioxide (saccharin, o-benzoic sulphimide) and its sodium salt	0
ex 29.31 B	4,4'-Sulphonyldiphenol with a purity of not less than 99,5 % by weight	0
ex 29.31 B	Aldicarb (ISO), dissolved in dichloromethane	0
ex 29.35 Q	Norfloxacin (INN)	0
ex 29.35 Q	Zotepine (INN)	4

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.35 Q	Ofloxacin (INN)	0
ex 29.35 Q	3'-Chloro-6'-cyclohexylaminospiro[isobenzofuran-1(3 <i>H</i>), 9'-xanthen]-3-one	0
ex 29.35 Q	6'-(<i>N</i> -Ethyl- <i>p</i> -toluidino)-2'-(<i>N</i> -methylanilino)spiro[isobenzofuran-1(3 <i>H</i>), 9'-xanthen]-3-one	0
ex 29.44 C	Cefamandole (INN) and its salts and esters	0
ex 30.02 A	German measles immunoplasma	0
ex 32.07 B	Inorganic colouring matter preparations mentioned in note 3 to Chapter 32, in hollow polyurethane spheres having a diameter of less than 200 micrometres	0
ex 32.09 A II and ex 39.01 C V	Polyurethane of 2,2'-(<i>tert</i> -butylimino)diethanol and 4,4'-methylenedi cyclohexyl isocyanate, dissolved in <i>N</i> , <i>N</i> -dimethylacetamide, with a polymer content of not less than 48 % by weight	0
ex 32.09 A II and ex 39.02 C XIV a)	Copolymer of <i>p</i> -cresol and divinylbenzene, dissolved in <i>N</i> , <i>N</i> -dimethylacetamide, with a polymer content of not less than 48 % by weight	0
ex 35.07	<i>Aspergillus</i> alkaline proteinase	0
ex 38.16	Unsterile blood serum obtained from the blood of a bovine foetus or non-immunized newly-born calf	0
ex 38.19 E	Monoalkylbenzenes, obtained by the alkylation of benzene with poly(ethylene) and having an average molecular weight of not less than 680 and not more than 820	0
ex 38.19 G	Catalysts, in the form of a powder, consisting of a mixture of titanium, magnesium and aluminium compounds on a carrier of silicon dioxide, containing by weight: — not less than 3 % and not more than 6 % of titanium — not less than 2 % and not more than 3 % of magnesium — not less than 0,3 % and not more than 0,5 % of aluminium, for use in the production of polyethylene with a density of at least 0,935 g/cm³ (a)	0
ex 38.19 G	Catalysts, consisting of dialkyldimethylammonium acetate containing chain lengths of 16 and 18 carbon atoms, suspended in organic solvents to a concentration of not less than 40 % by weight	0
ex 38.19 S	Doped silicon wafers, of Czochralski technology with a diameter of 70 mm or more, unpolished and with an oxygen content of not less than 5×10^{17} atoms per cm ³	0
ex 38.19 X	2,3-Bis [-2-(perfluoroalkyl)ethylthio] butane-1,4-diol	0
ex 39.01 C II a)	Polycondensation products of formaldehyde and a mixture of toluene-2-sulphonamide and toluene-4-sulphonamide	0
ex 39.01 C III a)	Polyester film, dyed in the mass, of a thickness of not more than 25 micrometres and metallized on one side	6

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.01 C III a)	Polycondensation products of terephthalic acid with a mixture of cyclohex-1,4-ylenedimethanol and ethane-1,2-diol in the form of a film	0
ex 39.01 C III a)	Polyester film having a thickness of not more than 70 micrometres, coated on one side with a substance which becomes coloured when heated to not more than 100 °C in the presence of salicyclic acid	0
ex 39.01 C III a)	Polyester film having a thickness of not more than 10 micrometres, coated on on side with salicyclic acid	0
ex 39.01 C III b)	Polycondensation products of terephthalic acid with a mixture of cyclohex-1,4-ylenedimethanol and ethane-1,2-diol, in one of the forms mentioned in Note 3 (b) to Chapter 39	0
ex 39.02 C I a)	Polyethylene, in one of the forms mentioned in Note 3(b) to Chapter 39, having a density of not less than 0,958 g/cm ³ at 23 °C and containing by weight not more than: — 50 ppm of aluminium — 2 ppm of calcium — 2 ppm of chromium — 2 ppm of iron — 2 ppm of nickel — 2 ppm of titanium — 8 ppm of vanadium for the manufacture of chlorosulphonated polyethylene (a)	0
ex 39.02 C I a)	Polyethylene, in one of the forms mentioned in note 3(b) to Chapter 39, having a density of not less than 0,945 and not more than 0,985 g/cm ³ for the manufacture of typewriter ribbon or similar ribbon (a)	0
ex 39.02 C VI a)	An A-B-A block copolymer of polystyrene, ethylene-butylene copolymer and polystyrene, containing not more than 35 % by weight of styrene, in one of the forms mentioned in note 3(b) to Chapter 39	0
ex 39.02 C VI b)	Plates, made from a copolymer of maleic anhydride and styrene, covered on both sides with a sheet of the abovementioned copolymer modified with a styrene-butadiene block copolymer, whether or not pigmented	0
ex 39.02 C XI	Polyvinyl alcohol film soluble in water at a temperature of 20 °C	0
ex 39.02 C XI	Polyvinyl butyral film having a graduated coloured band	6
ex 39.02 C XIV a)	Copolymers of vinylidene chloride and acrylonitrile, in the form of expandable beads of a diameter not less than 4 micrometres and not more than 20 micrometres	0
ex 39.02 C XIV a)	Ionomer resin consisting of a salt of a copolymer of ethylene and methacrylic acid	0
ex 39.02 C XIV a)	Ionomer resin consisting of a salt of a terpolymer of ethylene, isobutyl acrylate and methacrylic acid	0
ex 39.02 C XIV a)	Polymerization products of acrylic acid, with alkyl methacrylate and small quantities of other monomers for use as thickeners in the manufacture of textile printing pastes (a)	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.02 C XIV a)	Copolymers of vinyl alcohol with ethylene, in one of the forms mentioned in note 3(b) to Chapter 39	6
ex 39.02 C XIV a)	Copolymers of ethylene with acrylic acid, or with methacrylic acid, containing not less than 16 % and not more than 30 % of acrylic acid or methacrylic acid by weight, in one of the forms mentioned in Note 3(b) to Chapter 39	0
ex 39.02 C XIV b)	Film of a mixture of polyvinylidene fluoride and of an acrylic polymer having a thickness not less than 40 micrometres and not more than 60 micrometres	0
ex 39.02 C XIV b)	Sheet of a thickness of not less than 1 mm and not more than 3 mm, consisting of a copolymer of ethylene with chlorotrifluoroethylene, whether or not backed with a woven glass fibre fabric	0
ex 39.02 C XIV b)	Films and sheets of a copolymer of ethylene with chlorotrifluoroethylene with a thickness of not less than 12 and not more than 400 micrometres	0
ex 39.03 B V a) 2	Ethylhydroxyethylcellulose, insoluble in water	4
ex 39.03 B V a) 2	Hydroxypropylcellulose	0
ex 40.05 C	Strip, consisting of polybutadiene-acrylonitrile containing, in the mass, microspheres, laminated on the upper surface with a polyvinyl chloride sheet also containing microspheres	0
ex 48.07 C	Bleached paper, impregnated with acrylic resin and coated with poly(vinylidene chloride) or coated with acrylic resin, having a thickness of not less than 170 micrometres and not more than 320 micrometres and a weight per square metre of not less than 165 grams and not more than 210 grams	0
ex 51.02 A I	Monofil of polytetrafluoroethylene	0
ex 56.01 A	Acetalized, multicomponent spun fibres with a matrix fibril structure, consisting of emulsion polymerized polyvinyl alcohol and polyvinyl chloride	0
ex 59.03 B	Polyvinyl alcohol bonded fibre fabrics, with a thickness of not less than 200 micrometres and not more than 280 micrometres and of a weight of not less than 20 g/m ² and not more than 50 g/m ² whether or not impregnated or coated, in the piece or cut into rectangles	0
ex 59.17 A	Needle punched synthetic fibre felts on a woven synthetic fibre base coated or covered on one side with polytetrafluoroethylene film, for the manufacture of filtration products (a)	0
ex 70.07	Circular flat lead glass plates, ground and polished with worked edges and having: — a thickness of not less than 3,5 mm and not more than 5 mm — a diameter of not less than 135 mm and not more than 140 mm — a density of not less than 2,88 g/cm³, and — a transmission of not less than 87 % at a wavelength of between 450 nanometres and 800 nanometres for incorporation into video projectors (a)	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 70.11	Face plates made wholly of glass, having a diagonal dimension of not more than 61 cm and a raised edge intended for use in the manufacture of monochrome cathode ray tubes (a)	0
ex 70.11	Glass cones with a shaped edge and having a diagonal dimension of not more than 61 cm intended for use in the manufacture of monochrome cathode ray tubes (a)	0
ex 81.04 D I b)	Chromium, in the form of cathode chips, pellets or briquettes, which contains not more than 0,10 % by weight of total oxygen, not more than 0,015 % by weight of total aluminium and not more than 0,001 % by weight of aluminium compounds insoluble in boiling 5N hydrochloric acid and in boiling fuming perchloric acid, and evaluated as aluminium, for the production of alloy for the manufacture of the following parts of gas turbines and jet engines (a): — blades, fixed or movable, including their rings — vanes — nozzles	0
ex 81.04 F I	Unwrought hafnium having a purity of not less than 95 % by weight and a zirconium content of not more than 4,5 % by weight	0
ex 84.17 F II	Immersion tube (coils) bundles consisting of an assembly of plastic tubes terminating at each end in a honeycomb structure (end fitting) surrounded by a pipe connector	0
ex 84.18 C II b)	Parts of apparatus for catalytic conversion of nitrogen oxides into nitrogen and water, consisting of shaped and fired units in honeycomb structure of a mixture of vanadium oxides or vanadium sulphates and titanium dioxide or barium sulphate, or of vanadium oxide, tungsten (wolfram) oxide and titanium dioxide, contained in a metal framework	0
ex 84.18 C II b)	Parts of apparatus for catalytic conversion of oxides of nitrogen into nitrogen and into water, consisting of perforated plates coated with a mixture of oxides of vanadium, titanium and molybdenum in a metal framework	0
ex 84.53 B or ex 84.55 C	Optical reader for reading dot-matrix printing characters and converting them into electrical signals, comprising a read head containing an optical detector, an amplifier, a focusing lens and two lamps, linked by two flat cables to a central module of which the dimensions do not exceed 200 × 220 mm, comprising a printed circuit board on which are mounted a microprocessor, an image recognition circuit and an analog/digital converter	1
ex 84.55 C	Winchester or thin film technology magnetic heads for disc file peripherals, as well as carrying arms equipped with such magnetic heads, capable of recording to a density of not less than 10 tracks per millimetre	0
ex 84.55 C	Dot- matrix displays, whose external dimensions do not exceed 15 × 90 × 280 mm excluding cables and connectors consisting of a layer of liquid crystals between two glass sheets or plates with 30 720 dots (arranged in 64 lines and 480 columns), mounted on a printed-circuit board comprising electronic components providing drive functions, with or without cable and connector	0
ex 84.55 C	Dot- matrix displays consisting of a layer of liquid crystal between two glass sheets or plates with a maximum of 15 360 dots (arranged in 64 lines and 240 columns), complete with an interface electronics board in C-MOS technology whose exterior dimensions do not exceed 186 × 75 × 15 mm, with not more than 544 connecting areas	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 84.55 C	Magnetic read/write elements in thin film technology for the manufacture of magnetic heads for disc file peripherals, capable of recording to a density of not less than 10 tracks per mm, in the form of sheets measuring not more than 48 × 48 mm and containing not less than 200 elements or in the form of strips measuring not more than 4 × 48 mm and containing not less than 10 elements (a)	0
ex 84.55 C	Assemblies for automatic data-processing machines, consisting of two stacked substrate layers each with two static random-access memories of N-MOS (including H-MOS) technology (N-MOS—S-RAMs), in the form of monolithic integrated circuits each with a storage capacity of 2 K bits and with a total storage capacity of either 8 K × 1 bit, or 4 K × 2 bits, contained in a housing, the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 23 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 4598601 5121850 5121934 5121935 5122148 5123059 5123120 5123128 5123129 5123337 5123339 - or — other identification markings relating to assemblies complying with the abovementioned description	0
ex 84.55 C	Assemblies for automatic data-processing machines, comprising UV-erasable, programmable, read-only memories (EPROMs), with a storage capacity of 256 K bits, consisting of a multilayer substrate, the exterior dimensions of which do not exceed 17 × 39 mm, on which are mounted: — two UV-erasable, programmable, read-only memories (EPROMs), in the form of monolithic integrated circuits, each with a storage capacity of 128 K bits and a quartz window on the upper surface — a decoder in the form of a monolithic integrated circuit — a decoupling capacitor — two resistances The assemblies bear: — an identification marking either consisting of or including the following combination of figures and letters: - EDH 7832 MM-30 - or — other identification markings relating to assemblies complying with the abovementioned description	2
ex 84.55 C	Assemblies for automatic data-processing machines, comprising UV-erasable, programmable, read-only memories (EPROMs), with a storage capacity of 256 K bits, consisting of a multilayer substrate, the exterior dimensions of which do not exceed 17 × 39 mm, on which are mounted: — four UV-erasable, programmable, read-only memories (EPROMs), in the form of monolithic integrated circuits, each with a storage capacity of 64 K bits and a quartz window on the upper surface — one decoder in the form of a monolithic integrated circuit — one decoupling capacitor The assemblies bear: — an identification marking either consisting of or including the following combination of figures and letters:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 84.55 C (<i>cont'd</i>)	EDH 7832 MC-35 or — other identification markings relating to assemblies complying with the abovementioned description	2
ex 84.55 C	Assemblies for automatic data-processing machines, comprising static random-access memories of C-MOS technology (C-MOS S-RAMs) with a storage capacity of 32 K bits consisting of a multilayer substrate, the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins, on which are mounted: — two static random-access memories of C-MOS technology (C-MOS S-RAMs) in the form of monolithic integrated circuits each with a storage capacity of 16 K bits — a decoder in the form of a monolithic integrated circuit — a decoupling capacitor The assemblies bear: — an identification marking either consisting of or including one of the following combinations of figures and letters: EDH 8804 C-20 EDH 8804 CL-20 or — other identification markings relating to assemblies complying with the abovementioned description	2
ex 84.55 C	Assemblies for automatic data-processing machines, comprising static random-access memories of C-MOS technology (C-MOS S-RAMs) with a storage capacity of 64 K bits consisting of a multilayer substrate, the exterior dimensions of which do not exceed 17 × 39 mm, on which are mounted: — four static random-access memories of C-MOS technology (C-MOS S-RAMs) in the form of monolithic integrated circuits each with a storage capacity of 16 K bits — a decoder in the form of a monolithic integrated circuit — a decoupling capacitor The assemblies have not more than 28 connecting pins and bear: — an identification marking either consisting of or including one of the following combinations of figures and letters: EDH 8808 B-20 EDH 8808 C-10 EDH 8808 C-12 EDH 8808 C-15 EDH 8808 C-20 EDH 8808 CL-15 EDH 8808 CL-20 or — other identification markings relating to assemblies complying with the abovementioned description	2
ex 84.55 C	Assemblies for automatic data-processing machines, consisting of two stacked substrate layers each with two quasi-static random-access memories of N-MOS (including H-MOS) technology, other than dynamic (N-MOS (quasi-static RAMs) in the form of monolithic integrated circuits each with a storage capacity of 4 K bits and with a total storage capacity of either 16 K × 1 bit or 8 K × 2 bits, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 24 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 84.55 C (cont'd)	— an identification marking either consisting of or including one of the following combinations of figures: 4599766 4599767 4599768 4599769 4599770 4599771 4599772 4599773 4599774 4599893 - or — other identification markings relating to assemblies complying with the abovementioned description	0
ex 84.55 C	Assemblies for automatic data-processing machines comprising a UV-erasable, programmable, read-only memory (EPROM) with a storage capacity of 64 K bits and a static random-access memory of C-MOS technology (C-MOS S-RAMs) with a storage capacity of 32 K bits consisting of a multilayer substrate, the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins, on which are mounted: — one UV-erasable, programmable, read-only memory (EPROM) in the form of a monolithic integrated circuit, with a storage capacity of 64 K bits and with a quartz window on the upper surface — two static random-access memories of C-MOS technology (C-MOS S-RAMs) in the form of monolithic integrated circuits, each with a storage capacity of 16 K bits — one decoder in the form of a monolithic integrated circuit — one decoupling capacitor — two resistances The assemblies bear: — an identification marking either consisting of or including one of the following combinations of figures and letters: EDH 90804 BS-25 (15) EDH 90804 BS-30 (20) - or — other identification markings relating to assemblies complying with the abovementioned description	2
ex 84.55 C	Assemblies for automatic data-processing machines, consisting of two stacked substrate layers with one or two static random access memories of bipolar technology (bipolar S-RAMs) in the form of monolithic integrated circuits, each with a storage capacity of 1 K bits and with a maximum storage capacity of 4 K bits, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 23 connecting pins and bearing: — an identification marking, either consisting of or including one of the following combinations of figures: 770965 4599497 7379442 - or — other identification markings relating to assemblies complying with the abovementioned description	0
ex 84.55 C	Magnetic bubble memories with a storage capacity of not more than 4 megabits contained in a housing the exterior dimensions of which do not exceed 43 × 44 mm, with not more than 42 connecting pins or contact areas and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)									
ex 84.55 C (cont'd)	— an identification marking consisting of or including one of the following combinations of figures or figures and letters: <table><tr><td>BDL 0133</td><td>MBM 2011</td><td>FBM 64 DA</td></tr><tr><td>BDL 0134</td><td>MBM 2256</td><td>7110</td></tr><tr><td>BDN 0151</td><td>FBM 54 DB</td><td>7114-1</td></tr></table> or — other identification markings relating to magnetic bubble complying with the abovementioned description	BDL 0133	MBM 2011	FBM 64 DA	BDL 0134	MBM 2256	7110	BDN 0151	FBM 54 DB	7114-1	0
BDL 0133	MBM 2011	FBM 64 DA									
BDL 0134	MBM 2256	7110									
BDN 0151	FBM 54 DB	7114-1									
ex 84.55 C	Component forming the arithmetic/logic element of a central processing unit, comprising not more than nine printed circuit boards, the dimensions of which do not exceed 290 × 310 mm on each of which are mounted not more than 121 ECL gate arrays or ECL random access memories (ECL-RAMs) and combinations thereof contained in a framework the dimensions of which do not exceed 611 × 501 × 596 mm which serves as a housing and interconnector for the printed circuit boards, which bear: — an identification marking either consisting of or including one of the following combinations of figures and letters: <table><tr><td>CO1B 2675 E 500</td></tr><tr><td>CO1B 2675 H 500</td></tr><tr><td>CO1B 2675 H 501</td></tr><tr><td>CO1B 2675 H 502</td></tr><tr><td>CO1B 2675 H 503</td></tr><tr><td>CO1B 2675 H 504</td></tr></table> or — other identification markings relating to components complying with the abovementioned description	CO1B 2675 E 500	CO1B 2675 H 500	CO1B 2675 H 501	CO1B 2675 H 502	CO1B 2675 H 503	CO1B 2675 H 504	0			
CO1B 2675 E 500											
CO1B 2675 H 500											
CO1B 2675 H 501											
CO1B 2675 H 502											
CO1B 2675 H 503											
CO1B 2675 H 504											
ex 84.55 C	Display unit with maximum dimensions, excluding cables and connectors, of 15 × 115 × 290 mm, comprising two layers or sheets of glass enclosing 128 000 liquid-crystal dots arranged in 200 rows and 640 columns, fixed to a printed circuit fitted with electronic components performing control functions, with or without cables and connectors	0									
ex 84.59 B	Integrally forged, rough-turned components, with unit weights of more than 150 tonnes, for reactor pressure vessels	0									
ex 84.61 B	Hydraulic five-stage valve, with two magnetic valves for servo-control, consisting essentially of three plastic sections, for incorporation in water softening devices with automatic regeneration (throughflow and counterflow) with a maximum capacity of 650 L ion exchange volume (a)	0									
ex 84.63 B II	Integrally forged and roughly shaped generator and turbine shafts of a weight exceeding 215 tonnes	0									
ex 85.01 B I b)	DC electric motor, brushless, with a maximum torque of 0,20 N/m, with an incorporated electronic control plate, outside rotor with circular cross-section and maximum diameter of 95 mm, aluminium precision-made hub with inside diameter of 28,6 mm, speed of 300 or 360 rpm, supply voltage of 12 volts ± 10 %	0									
ex 85.01 B I b)	DC electric motor, brushless, with a maximum torque of 0,20 N/m, with outside rotor of a maximum diameter of 55 mm, coupling flange of a diameter of 77 mm and precision-made chuck of a diameter of 44 mm, four-phase winding, rated speed of 3 600 rpm, supply voltage 12 volts ± 10 % and fitted with wires and connectors	0									

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.01 B I b)	Two or three-phase DC electric motor, brushless, with a maximum torque of 0,20 N/m, with an external rotor of 62 mm maximum diameter and incorporating an electronic control panel, maximum dimensions 85 × 85 × 20 mm, including the shaft, nominal operating voltage of 12 volts ± 10 % and a rate of rotation of 300 rpm	0
ex 85.01 B I b)	Bipolar stepping motors with an angle of step of 1,8 degrees 200 steps per revolution, 2-phase rotation sequence with bipolar-type windings, maximum external dimensions of 39 × 39 × 20 or 25 mm excluding shaft, fixing screws and boss, with a minimum torque of 0,25 N/m for the version with a maximum height of 20 mm and 0,35 N/m for the version with a maximum height of 25 mm	0
ex 85.01 B I b)	Hybrid stepping motor, with an angle of step of 0,9°, 400 steps per revolution, 4-phase rotation sequence with bipolar-type winding, consisting of a rotor, of a laminated stator held between two square flanges, not more than 40 mm wide, fitted with biterminate shaft, wires and connectors	0
ex 85.01 B I b)	Hybrid stepping motor with an angle of step of 0,9°, 400 steps per revolution, 2-phase rotation sequence and bipolar windings, comprising a rotor and a stator encapsulated in a cylindrical housing with a maximum diameter of 47 mm and maximum thickness of 14 mm, fitted with a single shaft output and cables with connectors	0
ex 85.01 B I b)	Hybrid stepping motor with an angle of step of 0,9°, 400 steps per revolution and 2-phase rotation sequence, and bipolar windings, comprising a rotor, a laminated stator enclosed between two square section flanges with sides not exceeding 40 mm, an integral two or three-phase tachometer enclosed in a cap with a maximum diameter of 35 mm, and separate cables and connectors for the motor and tachometer outputs, with maximum dimensions of 40 × 40 × 62 mm, including the shaft	0
ex 85.01 B II	Static converter consisting of a combination of seven diodes in cascade, for output voltages of not less than 40 kV DC with a load current of not less than 3 mA	0
ex 85.03	Dry zinc/carbon batteries of a voltage of not less than 5,5 and not more than 6,5 and of a size not exceeding 110 × 90 × 5 mm, for incorporation in film cassettes for instant pictures (a)	0
ex 85.03	Lithium iodine single cell battery with dimensions of 45 × 9 × 23 mm and a voltage not exceeding 2,8	0
ex 85.13 B or ex 85.21 D II	Opto-electronic receiving device (PINFET receiver) with a wavelength range 1 300 – 1 600 nanometres, and a speed of not less than 678 megabits per second, in the form of a hybrid integrated circuit, contained in a housing the exterior dimensions of which do not exceed 25 mm × 13 mm × 13 mm, with not more than 16 connecting pins, with an attached optical fibre lead (pig-tail), and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: 416/7/97013 QDFI-XXXX-001 or — other identification markings relating to devices complying with the abovementioned description	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)																																																												
ex 85.18 B	Adjustable capacitor, in the form of a circular plate fitted with a screw head in its centre and two connecting tags, of a thickness not exceeding 3 mm and a capacity of from 5 to 30 picofarads, for the manufacture of products falling within Chapter 91 (a)	0																																																												
ex 85.19 A	Thermal relays contained in a hermetically sealed glass cartridge not exceeding 35 mm in length excluding wires, with a maximum leakage rate of 10^{-6} cm ³ He/sec at 1 bar in the temperature range 0 to 160 °C, to be incorporated into compressors for refrigerating equipment (a)	0																																																												
ex 85.19 A	Reed switches in the form of a glass capsule containing not more than three electrical contacts on metal arms and a small quantity of mercury	0																																																												
ex 85.19 C	Single-face printed circuit, of dimensions not exceeding 30 × 30 mm, for the manufacture of products falling within Chapter 91 (a)	0																																																												
ex 85.21 A V	Cathode-ray tubes with dot mask (so-called dot-mask technology), with electron guns arranged in triangular fashion (so-called delta technology), with a distance between the coloured dots of 0,31 mm, with devices for automatic convergence	0																																																												
ex 85.21 A V	Cathode-ray tubes with a memory (direct view storage tubes) for the reproduction of alphanumeric and analogue data, equipped with a scanning device, for reading the images	0																																																												
ex 85.21 A V	Colour cathode-ray tubes, using shadow mask, in-line technology in which images are displayed on a screen with a usable surface not exceeding 165 × 165 mm for use in electronic flight instrument, warning and systems displays (a)	0																																																												
ex 85.21 A V	Colour cathode ray tubes with a dot mask equipped with electron guns placed side by side (in-line technology) with a distance of less than 0,4 mm between colour dots and with at least one of the following characteristics: — a diagonal screen measurement of at least 48 cm, a diagonal angle of deflection of a most 90° and convergence errors of not more than 0,8 mm maximum in the corners — equipped with an inseparable cladding on the tubes for absorbing vibrations (potting system) — without internal magnetic screen — equipped with a phosphor layer calibrated with the following nominal coordinates for the colour dots: <table><tr><td></td><td><i>red</i></td><td><i>green</i></td><td><i>blue</i></td></tr><tr><td>X</td><td>0,64</td><td>0,29</td><td>0,15</td></tr><tr><td>Y</td><td>0,33</td><td>0,60</td><td>0,06</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,64</td><td>0,31</td><td>0,155</td></tr><tr><td>Y</td><td>0,34</td><td>0,595</td><td>0,07</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,610</td><td>0,307</td><td>0,150</td></tr><tr><td>Y</td><td>0,350</td><td>0,595</td><td>0,065</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,61</td><td>0,205</td><td>0,15</td></tr><tr><td>Y</td><td>0,35</td><td>0,680</td><td>0,065</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,62</td><td>0,29</td><td>0,15</td></tr><tr><td>Y</td><td>0,35</td><td>0,60</td><td>0,065</td></tr></table>		<i>red</i>	<i>green</i>	<i>blue</i>	X	0,64	0,29	0,15	Y	0,33	0,60	0,06	or				X	0,64	0,31	0,155	Y	0,34	0,595	0,07	or				X	0,610	0,307	0,150	Y	0,350	0,595	0,065	or				X	0,61	0,205	0,15	Y	0,35	0,680	0,065	or				X	0,62	0,29	0,15	Y	0,35	0,60	0,065	0
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(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)																																																												
ex 85.21 A V	Colour cathode ray tubes with a dot mask equipped with electron guns in a triangular fashion (delta technology) with a distance of less than 0,4 mm between colour dots, with at least one of the following characteristics: — a diagonal screen measurement of at least 66 cm — equipped with a phosphor layer calibrated with the following nominal coordinates for the colour dots: <table><tr><td></td><td><i>red</i></td><td><i>green</i></td><td><i>blue</i></td></tr><tr><td>X</td><td>0,64</td><td>0,29</td><td>0,15</td></tr><tr><td>Y</td><td>0,33</td><td>0,60</td><td>0,06</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,64</td><td>0,31</td><td>0,155</td></tr><tr><td>Y</td><td>0,34</td><td>0,595</td><td>0,07</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,610</td><td>0,307</td><td>0,150</td></tr><tr><td>Y</td><td>0,350</td><td>0,595</td><td>0,065</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,61</td><td>0,205</td><td>0,15</td></tr><tr><td>Y</td><td>0,35</td><td>0,680</td><td>0,065</td></tr><tr><td>or</td><td></td><td></td><td></td></tr><tr><td>X</td><td>0,62</td><td>0,29</td><td>0,15</td></tr><tr><td>Y</td><td>0,35</td><td>0,60</td><td>0,065</td></tr></table>		<i>red</i>	<i>green</i>	<i>blue</i>	X	0,64	0,29	0,15	Y	0,33	0,60	0,06	or				X	0,64	0,31	0,155	Y	0,34	0,595	0,07	or				X	0,610	0,307	0,150	Y	0,350	0,595	0,065	or				X	0,61	0,205	0,15	Y	0,35	0,680	0,065	or				X	0,62	0,29	0,15	Y	0,35	0,60	0,065	0
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X	0,62	0,29	0,15																																																											
Y	0,35	0,60	0,065																																																											
ex 85.21 A V	Displays in the form of a tube consisting of a glass housing mounted on a board the dimensions of which do not exceed 350 × 300 mm excluding leads. The tube contains one or more rows of characters or lines arranged in rows, each character or line consisting of fluorescent or phosphorescent elements. These elements are mounted on a metallized base which is covered with fluorescent substances or phosphorescent salts which give off light when bombarded with electrons	0																																																												
ex 85.21 A V	Flat screen monochrome cathode ray tubes having a diagonal screen measurement of not less than 142 mm and not more than 145 mm, a luminescence of between 300 and 400 lumen, a resolution of between 0,06 and 0,1 mm, phosphor types P 1 or P 55 or P 56, an anode voltage of more than 34 Kv, a focus voltage of more than 7 Kv and a cathode current of not less than 3 mA	0																																																												
ex 85.21 C	Quartz crystal oscillating at a frequency of 32 768 Hz, contained in a cylindrical housing of a length not exceeding 8,2 mm and a diameter not exceeding 3,2 mm, for the manufacture of products falling within Chapter 91 (a)	0																																																												
ex 85.21 D II	Digital displays of a size not exceeding 25 × 35 mm, consisting of a printed circuit board on which are mounted, under a plastic cover, up to 22 light-emitting diodes manufactured from gallium-based semi-conductor compounds. Each display consists of a single character with or without a plus or minus sign and/or one or two dots	0																																																												
ex 85.21 D II	Digital displays, consisting of a printed circuit board of a size not exceeding 35 × 90 mm with a single line of characters, not less than two in number, comprising light-emitting diodes made from gallium-based semi-conductor compounds mounted thereon. Each character is composed of up to eight segments with or without a decimal point and the line of characters has a protective cover of plastic	0																																																												

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Monolithic integrated circuits, consisting of eight independent elements capable of controlling the eight segments and/or characters of fluorescent or gas discharge displays, contained in a housing the exterior dimensions of which do not exceed 7×23 mm, with not more than 18 connecting pins and bearings: — an identification marking either consisting of or including one of the following combinations of figures: 513 514 534 594 6118 6128 6138 - or — other identification markings relating to circuits complying with the abovementioned description	0
ex 85.21 D II	Read-only memories (ROMs), in the form of a monolithic integrated circuit, with a storage capacity of $16\text{ K} \times 8$ bits, with read-register and serial output control, contained in a housing the exterior dimensions of which do not exceed 50×16 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of one of the following combinations of figures or including one of those combinations: - from 62000 to 62999 - or — other identification markings relating to ROMs complying with the abovementioned description	0
ex 85.21 D II	Read-only memory in C-MOS technology (C-MOS ROM) with a storage capacity of 256 K bits and a standby current of not more than 0,03 mA, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17×50 mm, with not more than 54 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: - HN 61256 - HN 613256 - MB 83256 - or — other identification markings relating to C-MOS ROMs complying with the abovementioned description	7
ex 85.21 D II	Read-only memory of C-MOS technology (C-MOS ROM) with a storage capacity of 1 megabit in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17×39 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: - HN 62301 P - MB 831124 - TC 531000 P - or — other identification markings relating to C-MOS ROMs complying with the abovementioned description	7

CCT heading No	Description	Rate of autonomous duty (%)																																																																																																												
ex 85.21 D II	Programmable, non-erasable, read-only memories (PROMs) of Schottky TTL technology, with a storage capacity of 2 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins or contact areas, and bearing: — an identification marking either consisting of one of the following combinations of figures or figures and letters or including one of those combinations: <table><tr><td>27 S 12</td><td>5305</td><td>6305</td><td>76 LS 03</td></tr><tr><td>27 S 13</td><td>5306</td><td>6306</td><td>7620</td></tr><tr><td></td><td>5308</td><td>6308</td><td>7621</td></tr><tr><td>28 L 22</td><td>5309</td><td>6309</td><td></td></tr><tr><td>28 LA 22</td><td>53 S 240</td><td>63 S 240</td><td>82 S 114</td></tr><tr><td>28 L2 XMFC</td><td>53 S 241</td><td>63 S 241</td><td>82 S 130</td></tr><tr><td></td><td></td><td>6335</td><td>82 S 131</td></tr><tr><td>29613</td><td>54 S 570</td><td>6336</td><td></td></tr><tr><td>29770</td><td>54 S 571</td><td></td><td>93436</td></tr><tr><td>29771</td><td></td><td>7053</td><td>93446</td></tr><tr><td></td><td>5604</td><td>7058</td><td></td></tr><tr><td>38510</td><td>5624</td><td></td><td>MB 7115</td></tr><tr><td></td><td></td><td>74 S 570</td><td>MB 7116</td></tr><tr><td></td><td></td><td>74 S 571</td><td>MB 7117</td></tr><tr><td></td><td></td><td></td><td>MB 7118</td></tr></table> or — other identification markings relating to PROMs complying with the abovementioned description	27 S 12	5305	6305	76 LS 03	27 S 13	5306	6306	7620		5308	6308	7621	28 L 22	5309	6309		28 LA 22	53 S 240	63 S 240	82 S 114	28 L2 XMFC	53 S 241	63 S 241	82 S 130			6335	82 S 131	29613	54 S 570	6336		29770	54 S 571		93436	29771		7053	93446		5604	7058		38510	5624		MB 7115			74 S 570	MB 7116			74 S 571	MB 7117				MB 7118	0																																																
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28 LA 22	53 S 240	63 S 240	82 S 114																																																																																																											
28 L2 XMFC	53 S 241	63 S 241	82 S 130																																																																																																											
		6335	82 S 131																																																																																																											
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ex 85.21 D II	Programmable, non-erasable, read-only memories (PROMs) with a storage capacity of 4 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins or 28 contact areas and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters: <table><tr><td>18 S 42</td><td>29620</td><td>54 S 472</td><td>74 S 472</td></tr><tr><td>18 S 46</td><td>29621</td><td>54 S 473</td><td>74 S 473</td></tr><tr><td>18 SA 42</td><td>29622</td><td>54 S 474</td><td>74 S 474</td></tr><tr><td>18 SA 46</td><td>29623</td><td>54 S 475</td><td>74 S 475</td></tr><tr><td></td><td>29624</td><td>54 S 476</td><td>74 S 476</td></tr><tr><td>24 S 41</td><td>29625</td><td>54 S 477</td><td>74 S 477</td></tr><tr><td>24 SA 41</td><td>29626</td><td>54 S 572</td><td>74 S 572</td></tr><tr><td></td><td>29627</td><td>54 S 573</td><td>74 S 573</td></tr><tr><td>27 S 15</td><td></td><td>54740</td><td></td></tr><tr><td>27 S 25</td><td>3604</td><td>54741</td><td>7640</td></tr><tr><td>27 S 26</td><td>3624</td><td></td><td>7641</td></tr><tr><td>27 S 27</td><td>3625</td><td>5605</td><td>7642</td></tr><tr><td>27 S 28</td><td></td><td>5625</td><td>7643</td></tr><tr><td>27 S 29</td><td>38510</td><td></td><td>7644</td></tr><tr><td>27 S 30</td><td></td><td>6340</td><td>7645</td></tr><tr><td>27 S 31</td><td>5340</td><td>6341</td><td>7646</td></tr><tr><td>27 S 32</td><td>5341</td><td>63 S 440</td><td>7647</td></tr><tr><td>27 S 33</td><td>53 S 440</td><td>63 RA 441</td><td>7648</td></tr><tr><td></td><td>53 RA 441</td><td>63 RS 441</td><td>7649</td></tr><tr><td>28 L 42</td><td>53 RS 441</td><td>63 S 441</td><td></td></tr><tr><td>28 L 45</td><td>53 S 441</td><td>6348</td><td>82 HS 137</td></tr><tr><td>28 L 46</td><td>5348</td><td>6349</td><td>82 HS 147</td></tr><tr><td>28 P 42</td><td>5349</td><td>6350</td><td>82 S 115</td></tr><tr><td>28 P 45</td><td>5350</td><td>6351</td><td>82 S 136</td></tr><tr><td>28 R 45</td><td>5351</td><td>6352</td><td>82 S 137</td></tr><tr><td>28 S 4 XFD</td><td>5352</td><td>6353</td><td>82 S 140</td></tr><tr><td>28 SA 41</td><td>5353</td><td></td><td>82 S 141</td></tr></table>	18 S 42	29620	54 S 472	74 S 472	18 S 46	29621	54 S 473	74 S 473	18 SA 42	29622	54 S 474	74 S 474	18 SA 46	29623	54 S 475	74 S 475		29624	54 S 476	74 S 476	24 S 41	29625	54 S 477	74 S 477	24 SA 41	29626	54 S 572	74 S 572		29627	54 S 573	74 S 573	27 S 15		54740		27 S 25	3604	54741	7640	27 S 26	3624		7641	27 S 27	3625	5605	7642	27 S 28		5625	7643	27 S 29	38510		7644	27 S 30		6340	7645	27 S 31	5340	6341	7646	27 S 32	5341	63 S 440	7647	27 S 33	53 S 440	63 RA 441	7648		53 RA 441	63 RS 441	7649	28 L 42	53 RS 441	63 S 441		28 L 45	53 S 441	6348	82 HS 137	28 L 46	5348	6349	82 HS 147	28 P 42	5349	6350	82 S 115	28 P 45	5350	6351	82 S 136	28 R 45	5351	6352	82 S 137	28 S 4 XFD	5352	6353	82 S 140	28 SA 41	5353		82 S 141	
18 S 42	29620	54 S 472	74 S 472																																																																																																											
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28 L 45	53 S 441	6348	82 HS 137																																																																																																											
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28 S 4 XFD	5352	6353	82 S 140																																																																																																											
28 SA 41	5353		82 S 141																																																																																																											

CCT heading No	Description				Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	28 S 42	HM 6641	82 S 142		0
	28 SA 42		82 S 146		
	28 S 45	7054	82 S 147		
	28 S 46	7059			
	28 SA 46		93438		
		7121	93448		
		7122	93452		
		7123	93453		
		7124			
		7125			
		7126			
		7226			
	or				
	— other identification markings relating to PROMs complying with the abovementioned description				
ex 85.21 D II	Programmable, non-erasable read-only memories (PROMs) with a storage capacity of 8 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins or 28 contact points and bearing:				0
	— an identification marking either consisting of one of the following combinations of figures and letters or including one of those combinations:				
	24 S 81	3628	74 LS 478	82707	
	24 SA 81		74 S 2708	82708	
	24 S 86	5380	74 S 454	82 HS 185	
		5381	74 S 455	82 LS 180	
	27 S 180	5388	74 S 478	82 LS 181	
	27 S 181	5389	74 S 479	82 S 180	
	27 S 185	53 S 840		82 S 181	
	27 S 35	53 S 841	7608	82 S 182	
			7680	82 S 183	
	28 L 85	54 LS 478	7681	82 S 184	
	28 L 86	54 S 2708	7684	82 S 185	
	28 P 85	54 S 454	7685	82 S 2708	
	28 R 35	54 S 455	7686		
	28 R 85	54 S 478	7687	87 S 180	
	28 S 2708	54 S 479	7688	87 S 181	
	28 S 85		7689	87 S 184	
	28 S 86	6380		87 S 185	
	28 SA 86	6381	77 S 180	87 S 186	
	28 S 8 XMFE	6388	77 S 181	87 S 187	
		6389	77 S 184		
	29623	63 S 840	77 S 185	93450	
	29630	63 S 841	77 S 186	93451	
	29631		77 S 187	93460	
	29632	7050		93461	
	29633	7055	TBPS 81 M	93465	
	29634	7060		93466	
	29635			93 L 450	
	29636	7127		93 L 451	
	29637	7128			
	29650	7129		9460	
	29651	7130			
	29652	7131			
	29653	7132			
		7232			
	or				
	— other identification markings relating to PROMs complying with the abovementioned description				

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	UV-erasable, programmable, read-only memories (EPROMs) with a storage capacity of 2 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with a quartz window on the upper surface and bearing: — an identification marking either consisting of one of the following combinations of figures or including one of the following combinations: AMI 702 ADC 82140 PP or — other identification markings relating to EPROMs complying with the abovementioned description	4
ex 85.21 D II	UV-erasable, programmable, read-only memory (EPROM) equipped with a programmable input/output system, with a storage capacity of 2 K × 8 bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 15 × 52 mm, with a quartz window on the upper face and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: D 8755 A TMP 8755 AC or — other identification marking relating to memories complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable, read-only memories (E²PROMs) with a storage capacity of 256 bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 10 × 12 mm, with not more than eight connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: NMC 9306 or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable programmable, read-only memories (E²PROMs) with a storage capacity of 4 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 33 mm, with not more than 24 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: X 2804 A X 2404 X 24 C 04 or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable, read-only memories (E²PROMs) with a storage capacity of 16 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking consisting of or including one of the following combination of figures and letters: X 24 C 16 X 2816 A 52 B 13 52 B 13 H or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable, read-only memories (E²PROMs) with a storage capacity of 64 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking consisting of or including one of the following combination of figures and letters: X 2864 A MCM 2864 52 B 33 52 B 33 H or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable, read-only memories (E²PROMs) with a storage capacity of 128 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking consisting of or including the following combination of figures and letters: X 28128 A or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable, read-only memories (E²PROMs) with a storage capacity of 256 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking consisting of or including the following combination of figures and letters: 28256 28 C 256 48 C 256 or — other identification markings relating to E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Static, random-access memories of TTL technology (TTL S-RAMs) with a storage capacity of 1 K bit, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 30 mm, with not more than 22 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)																											
ex 85.21 D II (<i>cont'd</i>)	— an identification marking either consisting of or including one of the following combinations of figures and letters: <table> <tr> <td>2205</td><td>74 LS 214</td><td>93412</td></tr> <tr> <td></td><td>74 LS 215</td><td>93 L 412</td></tr> <tr> <td>2510</td><td>74 LS 314</td><td>93415</td></tr> <tr> <td>2511</td><td>74 LS 315</td><td>93 L 415</td></tr> <tr> <td></td><td>74 S 207</td><td>93422</td></tr> <tr> <td></td><td>74 S 208</td><td>93 L 422</td></tr> <tr> <td></td><td>74 S 214</td><td>93425</td></tr> <tr> <td></td><td>74 S 314</td><td>93 F 425</td></tr> <tr> <td></td><td></td><td>93 L 425</td></tr> </table> or — other identification markings relating to TTL S-RAMs complying with the abovementioned description	2205	74 LS 214	93412		74 LS 215	93 L 412	2510	74 LS 314	93415	2511	74 LS 315	93 L 415		74 S 207	93422		74 S 208	93 L 422		74 S 214	93425		74 S 314	93 F 425			93 L 425	0
2205	74 LS 214	93412																											
	74 LS 215	93 L 412																											
2510	74 LS 314	93415																											
2511	74 LS 315	93 L 415																											
	74 S 207	93422																											
	74 S 208	93 L 422																											
	74 S 214	93425																											
	74 S 314	93 F 425																											
		93 L 425																											
ex 85.21 D II	Static, random-access memories of N-MOS (including H-MOS) technology (N-MOS S-RAMs) with a storage capacity of 1 K × 4 bits and access time not exceeding 70 ns, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 8 × 23 mm, with not more than 18 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: AM 2149 PD 2149 SY 2149 H TMS 2149 or — other identification markings relating to N-MOS S-RAMs complying with the abovementioned description	7																											
ex 85.21 D II	Static, random-access memories of C-MOS technology (C-MOS S-RAMs), with a storage capacity of 4 K × 1 bit, a maximum access time not exceeding 70 ns and a standby mode supply current of less than 1 mA, in the form of a monolithic integrated circuit, contained in a housing the dimensions of which do not exceed 9 × 26 mm, with 18 connecting pins, and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: 6147 MCM 61 L 47 or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	0																											
ex 85.21 D II	Static, random-access memory of C-MOS technology (C-MOS S-RAM) with a storage capacity of 2 K × 8 bits and with a maximum standby power of 0,005 milliwatts at 25 °C in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 33 mm with not more than 24 connecting pins and bearing: — an identification marking consisting of or including one of the following combination of figures and letters: TC 5516 A or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	7																											

CCT heading No	Description	Rate of autonomous duty (%)												
ex 85.21 D II	Static, random-access memories of N-MOS (including H-MOS) technology (N-MOS S-RAMs) with a storage capacity of 8 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters: <table><tr><td>4008</td><td>8104</td></tr><tr><td></td><td>8108</td></tr><tr><td>4118</td><td>8112</td></tr><tr><td></td><td>8114</td></tr><tr><td>PD 421</td><td>8185</td></tr><tr><td>4801</td><td></td></tr></table> or — other identification relating to N-MOS S-RAMs complying with the abovementioned description	4008	8104		8108	4118	8112		8114	PD 421	8185	4801		0
4008	8104													
	8108													
4118	8112													
	8114													
PD 421	8185													
4801														
ex 85.21 D II	Static, random-access memories of N-MOS (including H-MOS) technology (N-MOS S-RAMs), in the form of a monolithic integrated circuit consisting of two stacked substrate layers each with two chips, each having a storage capacity of 2 K bits and with a total storage capacity of 8 K × 1 bit or 4 K × 2 bits, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 23 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: <table><tr><td>4598601</td></tr><tr><td>5121850</td></tr><tr><td>5121934</td></tr><tr><td>5121935</td></tr><tr><td>5122148</td></tr><tr><td>5123059</td></tr><tr><td>5123120</td></tr><tr><td>5123128</td></tr><tr><td>5123129</td></tr><tr><td>5123337</td></tr><tr><td>5123339</td></tr></table> or — other identification markings relating to N-MOS S-RAMs complying with the abovementioned description	4598601	5121850	5121934	5121935	5122148	5123059	5123120	5123128	5123129	5123337	5123339	0	
4598601														
5121850														
5121934														
5121935														
5122148														
5123059														
5123120														
5123128														
5123129														
5123337														
5123339														
ex 85.21 D II	Static, random-access memories of N-MOS (including H-MOS) technology (N-MOS S-RAMs) with a storage capacity of 256 × 4 bits with access time not exceeding 25 nano seconds in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters: <table><tr><td>9122 – 25</td></tr><tr><td>91 L 22 – 25</td></tr></table> or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	9122 – 25	91 L 22 – 25	0										
9122 – 25														
91 L 22 – 25														

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Static, random-access memories of C-MOS technology (C-MOS S-RAMs) with a storage capacity of 64 K bits in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 18 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking consisting of the following combination of figures and letters or including one of those combinations: TC 5564 MB 8464 TC 5565 C MCM 6164 HM 6264 P HM 6264 LFP HM 6264 MB 81 C 71 or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	0
ex 85.21 D II	Monolithic integrated circuit consisting of a static, random-access memory (S-RAM) with a storage capacity of 256 bits superimposed bit-for-bit on a programmable, electrically erasable, read-only memory (E²PROM), contained in a housing the exterior dimensions of which do not exceed 8 × 24 mm, with not more than 18 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: X 2210 X 2443 X 2444 or — other identification markings relating to S-RAMs superimposed of E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Monolithic integrated circuit consisting of a static, random-access memory (S-RAM) with a storage capacity of 2 K bit, superimposed bit-for-bit on an electrically erasable, programmable, read-only memory (E²PROM), contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of the following combinations of figures and letter: X 2002 or — other identification markings relating to S-RAMs stacked on E²PROMs complying with the abovementioned description	0
ex 85.21 D II	Monolithic integrated circuit consisting of a static, random-access memory (S-RAM) with a storage capacity of 4 K bits, superimposed bit-for-bit on an electrically erasable, programmable, read-only memory (E²PROM), contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of the following combination of figures and letter: X 2004 or — other identification markings relating to SRAMs stacked on E²PROMs complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	'Quasi-static' random-access memories of N-MOS (including H-MOS) technology (N-MOS quasi-static RAMs), in the form of a monolithic integrated circuit consisting of two stacked substrate layers, each with two chips, each having a storage capacity of 4 K bits and with a total storage capacity of 16 K × 1 bit or 8 K × 2 bits, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 4599766 4599769 4599772 4599893 4599767 4599770 4599773 4599768 4599771 4599774 or — other identification markings relating to N-MOS quasi-static RAMs complying with the abovementioned description	0
ex 85.21 D II	Random access memories of ECL technology (ECL-RAMs) with a storage capacity of 4 K bits, in the form of a monolithic integrated circuit, contained in a housing whose exterior dimensions do not exceed 11 × 32 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures or figures and letters: PB 10474 10470 100474 10474 or — other identification markings relating to ECL-RAMs complying with the abovementioned description	0
ex 85.21 D II	Field programmable array logics (PALs) of bipolar technology, in the form of a monolithic integrated circuit, with fusible links, a programmable AND array, fixed OR array, not more than 20 inputs and not more than 10 outputs, whether or not with registers, contained in a housing the exterior dimensions of which do not exceed 19 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including the following combinations of figures and letters: 10 H 8 16 A 4 18 L 4 10 L 8 16 C 1 16 H 2 20 C 1 12 H 6 16 L 2 20 L 2 12 L 6 16 L 6 20 L 10 20 R 4 12 L 10 16 L 8 20 X 4 16 R 4 20 X 8 14 H 4 16 R 6 20 X 10 14 L 4 16 R 8 14 L 8 16 X 4 or — other identification markings relating to PALs complying with the abovementioned description	5
ex 85.21 D II	Programmable, non-erasable, logic circuits (field programmable logic array) of TTL Schottky technology, with not more than 48 AND functions, not more than eight OR functions, and not more than 16 inputs, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	FP 54 AS 839 FP 74 AS 839 82 S 100 FP 54 AS 840 FP 74 AS 840 82 S 101 SN 54 LS 333 SN 74 LS 333 SN 54 LS 334 SN 74 LS 334 93458 SN 54 LS 335 SN 74 LS 335 93459 SN 54 LS 336 SN 74 LS 336 or — other identification markings relating to programmable field logic arrays complying with the abovementioned description	5
ex 85.21 D II	Semi-custom logic array (Gate arrays) of C-MOS technology, in the form of a monolithic integrated circuit, with not less than 8 000 2-input NAND functions, contained in a housing the exterior dimensions of which do not exceed 39 × 39 mm, with not less than 179 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: MB 66000 VH or — other identification markings relating to C-MOS logic arrays complying with the abovementioned description	0
ex 85.21 D II	Video gate arrays programmed to control graphics and memory, in the form of a monolithic integrated circuit contained in a housing whose exterior dimensions do not exceed 15 × 52 mm, with not more than 40 connecting pins and bearing: — an identification marking consisting of or including the following combination of letters: PVGA or — other identification markings relating to programmed gate arrays complying with the abovementioned description	0
ex 85.21 D II	Single-chip microcomputers, in the form of a monolithic integrated circuit, consisting of an arithmetical unit with a capacity of four bits plus a read-only memory (ROM) with a capacity of not less than 18 K bits and not more than 65 K bits and a random-access memory (RAM) with a capacity of not less than 512 bits and not more than 4 K bits, contained in a housing the exterior dimensions of which do not exceed 17 × 58 mm, with not more than 80 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: CD 3200-3299 TP 0310-03299 HD 38800 TP 0450-04599 HD 38820 TMC 0270-0279 TP 0480-04899 HD 44796 TMC 0500-0599 TP 0500-05999 HD 44800 TMC 0980-0989 HD 44801 TMC 1500-1599 HD 44820 TMC 1980-1999 HD 44840 HD 44860 HD 614042 or — other identification markings relating to single-chip microcomputers complying with the abovementioned description	0
ex 85.21 D II	Central processing unit of N-MOS (including H-MOS) technology (N-MOS CPU), in the form of a monolithic integrated circuit consisting of a 16 × 16 bit service memory, a 16 × 20 bit service memory, a 32 × 32 bit service memory, an 8 × 8 bit service memory, a 16 bit register,	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	two 20 bit registers, an 8 bit register, one 12 bit register, a 5 bit counter and timing network, contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: LSI-604041855 - or — other identification markings relating to N-MOS central processing units complying with the abovementioned description	0
ex 85.21 D II	Contention resolving local area network (LAN) controllers, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 63 × 16 mm, with not more than 48 connecting pins, and bearing: — an identification marking either consisting of the following combinations of figures or figures and letters or including one of those combinations: MCM 68590 AM 7990 8001 8003 82586 - or — other identification markings relating to contention resolving local area network controllers complying with the abovementioned description	0
ex 85.21 D II	Hard-disc controllers of N-MOS (including H-MOS) technology (N-MOS HDCs), in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 15 × 53 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: WD 1010 WD 2010 PD 7261 - or — other identification markings relating to N-MOS HDCs complying with the abovementioned description	0
ex 85.21 D II	Arithmetic-logic units of N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of one 32 bit register, one 24 bit register, one 4 bit register, twelve 1 bit registers, two 16 × 24 bit service memories, one logic network performing arithmetic and logic operations, decodifying logic, an error detection and management logic, one 8 bit counter and a timing network, contained in a housing the exterior dimensions of which do not exceed 23 × 82 mm, with not more than 64 connecting pins and bearing: — the identification marking: ALU 0486 - or — other identification markings relating to arithmetic-logic units complying with the abovementioned description	0
ex 85.21 D II	Logic control circuits of N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of one 7 bit register, three timers, one multiplexer sequential and combining networks intended to perform control operations, decodifying logic, error detection	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	and management logic and a timing network, contained in a housing the exterior dimensions of which do not exceed 23 × 82 mm, with not more than 64 connecting pins and bearing: — the identification marking: MIC 0482 - or — other identification markings relating to logic control circuits complying with the abovementioned description	0
ex 85.21 D II	Logic circuit of N-MOS (including H-MOS) technology (N-MOS LC) serving as a clock generator for central process unit, main memory and input/output interfaces, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: H 108982 (MCC) - or — other identification markings relating to N-MOS logic circuits (N-MOS LCs) complying with the abovementioned description	0
ex 85.21 D II	Sequence control circuits of N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of one 32 bit register, three 16 bit registers, one 16 × 16 bit service memory, one 7 × 17 bit last-in first-out (LIFO) memory, one adder circuit, decodifying logic, priority logic, error detection and management logic, one 16 bit multiplexer, one 8 bit counter and a timing network, contained in a housing the exterior dimensions of which do not exceed 23 × 82 mm, with not more than 64 connecting pins and bearing: — the identification marking: CSS 0484 - or — other identification markings relating to sequence control circuits complying with the abovementioned description	0
ex 85.21 D II	Error correction and detection unit (ECDU) of bipolar technology, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 62 mm, with not more than 48 connecting pins and bearing: — an identification marking either consisting of or including the following combinations of figures and letters: 2960 74 F 630 74 F 631 DP 8400 74 LS 630 74 LS 631 - or — other identification markings relating to error correction and detection units (ECDUs) complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Error detection and correction circuit of N-MOS (including H-MOS) technology capable of detecting and correcting single bit errors and detecting all double bit errors, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 contact areas and bearing: — an identification marking either consisting of or including the following combination of figures: 8206 or — other identification markings relating to N-MOS error detection and correction circuits complying with the abovementioned description	0
ex 85.21 D II	Burst error processor (BEP) of N-MOS (including H-MOS) technology for detecting and correcting multiple errors derived from a line of magnetic discs, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 54 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: Z 8065 AM 9520 AM 9521 or — any other identification marking relating to N-MOS burst error processor complying with the abovementioned description	0
ex 85.21 D II	Electronic control circuit of bipolar technology in the form of a monolithic integrated circuit for the control of dynamic random-access memories (D-RAMs), capable of multiplexing address and generating timing, contained in a housing the exterior dimensions, of which do not exceed 17 × 62 mm, with not more than 48 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: DP 8408 DP 8409 MB 1422 or — other identification markings relating to electronic control circuits complying with the abovementioned description	0
ex 85.21 D II	N-MOS (including H-MOS) programmable communication interfaces (N-MOS PCIs), in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letter: 8251 A or — other identification markings relating to N-MOS PCIs complying with the abovementioned description	7
ex 85.21 D II	Enhanced programmable communications interface (EPCI), in the form of a monolithic integrated circuit, contained in a housing the external dimensions of which do not exceed 16 × 38 mm, with not more than 28 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking either consisting of or including the following combination of figures: 2661 or — other identification markings relating to EPCIs complying with the abovementioned description	0
ex 85.21 D II	Serial interfaces, capable of implementing the data stream encoding, decoding and associated control functions for a local area network, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 33 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of the following combination of figures or figures and letters or one of those combinations: AM 7991 8002 8023 82501 or — other identification markings relating to serial interface devices complying with the abovementioned description	0
ex 85.21 D II	Station digital interface circuit for parallel/serial or serial/parallel conversion of digital signals in telephone sets, of C-MOS technology (C-MOS STID), in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins, and bearing: — an identification marking consisting of or including the following combination of figures and letters: WCC 295 G or — other identification markings referring to station interface digital circuits complying with the abovementioned description	0
ex 85.21 D II	N-MOS (including H-MOS) programmable interval timers (N-MOS PITs), in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 8253 8254 or — other identification markings relating to N-MOS PITs complying with the abovementioned description	6
ex 85.21 D II	Demodulator/tone decoder of bipolar technology for frequency decoding, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 10 × 21 mm, with not more than 14 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: XR 2211 or — other identification markings relating to demodulator tone decoders complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	C-MOS clock circuits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 54 mm, with more than 16 connecting pins, and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: HI 2060 HI 2065 MSM 5537 T 3605 or — other identification markings relating to clock circuits complying with the abovementioned description for the production of automatic time-switches, instrument panel clocks and clocks of a similar type for motor vehicles (a)	0
ex 85.21 D II	C-MOS clock circuits, operating from a single 1,5 V power supply, with a liquid crystal display (LCD) driver, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 15 × 21 mm, with not more than 56 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: TC 8219 AF or — other identification markings relating to C-MOS clock circuits complying with the abovementioned description	0
ex 85.21 D II	Amplifier, in the form of a monolithic integrated analogue circuit, contained in a housing the dimensions of which do not exceed 2 × 4 × 4 mm, with not more than 10 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: V 35 C 05 or — other identification markings relating to amplifiers complying with the abovementioned description This amplifier is for the manufacture of products falling within subheading 90.19 B I (a)	0
ex 85.21 D II	Transceivers with four channels (Quad bus) of ALP Schottky technology with on-chip D type registers and internal ODD 4 bit parity generator/checker, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 9 × 28 mm, with not more than 20 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: AM 2907 or — other identification markings relating to transceivers (Quad bus) complying with the abovementioned description	0
ex 85.21 D II	Four-line drivers of advanced, low-power Schottky technology, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 20 × 7 mm, with not more than 16 connecting pins and bearing:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking consisting of or including one of the following combinations of figures and letters: AM 26LS29 AM 26LS31 SN 75172 SN 75174 or — other identification markings relating to four-line drivers of ALPS technology complying with the abovementioned description	0
ex 85.21 D II	Universal Synchronous/Asynchronous Receiver/Transmitter (USART) of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: MSM 82 C 51 or — other identification markings relating to Universal Synchronous/Asynchronous Receiver/Transmitters complying with the abovementioned description	7
ex 85.21 D II	8 bit microprocessor of N-MOS (including H-MOS) technology with 16 bit internal architecture, in the form of a monolithic integrated circuit consisting of a central processing unit (CPU), a timing generator, two independent DMA channels, a programmable interrupt controller, three programmable 16 bit timers, programmable memory and peripheral chip select, a programmable wait state generator and a local bus controller, contained in a housing the dimensions of which do not exceed 30 × 30 mm with not more than 68 contact areas, and bearing: — an identification marking consisting of or including the following combination of figures: 80188 or — other identification markings relating to microprocessors complying with the abovementioned description	7
ex 85.21 D II	16 bit microprocessor of bipolar technology, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 25 × 82 mm, with not more than 68 connecting pins or contact areas and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: AM 29116 SBP 9989 or — other identification markings relating to microprocessors complying with the abovementioned description	0
ex 85.21 D II	16 bit microprocessor in N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of a central processing unit (CPU), a timing generator, two independent DMA channels, a programmable interrupt controller, three programmable 16 bit	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	timers, programmable memory and external chip selection logic, a programmable wait state generator with bus control unit, contained in a housing the exterior dimensions of which do not exceed 30 × 30 mm, with not more than 68 connecting pins or contact areas and bearing: — an identification marking consisting of or including the following combination of figures: 80186 - or — other identification markings relating to microprocessors complying with the above description	0
ex 85.21 D II	Numeric processor extension unit of N-MOS (including H-MOS) technology (N-MOS NPX) containing not more than 14 registers, in the form of a monolithic integrated circuit, contained in a package the exterior dimensions of which do not exceed 15 × 52 mm, with not more than 40 connecting pins and bearing: — an identification marking consisting of or including one of the following combination of figures: 8087-3 TX 32081 W 8087-2 80287 - or — other identification markings, relating to N-MOS NPXs complying with the abovementioned description	0
ex 85.21 D II	Floppy-disc data separator (FDDS), in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 27 × 8 mm, with not more than 20 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: FDC 9216 FDC 9216-B WD 9216-00 WD 9216-01 FDC 9229 T FDC 9229 BT - or — other identification markings relating to FDDS, complying with the abovementioned description	0
ex 85.21 D II	C-MOS-phoneme speech synthesizer, with a supply current of less than 10 mA, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: CM 54104 CM 54166 N2L CD 54123 N2L CM 54145 N2L CD 54121 N2L CD 54147 N2L CM 54146 N2L CD 54122 N2L SC 01 SS 1263 - or — other identification markings relating to phoneme speech synthesizers complying with the abovementioned description	0
ex 85.21 D II	Triple video digital to analogue converter (VDAC), each channel having a capacity of not more than 8 bits with a maximum conversion time of not more than 25 nanoseconds, in the form of a hybrid or monolithic integrated circuit whether or not incorporating three random access	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	memories (RAMs) each with a storage capacity of not more than 2 K bits, contained in a housing the exterior dimensions of which do not exceed 54 × 62 mm, with not more than 61 connecting pins and bearing: — an identification marking consisting of one of the following combinations of letters and figures: VDAC 444 TD TDC 1334 RGB DAC 4 T HDAC 34010 RGB DAC 8 E HDAC 34020 RGB DAC 8 T - or — other identification markings relating to triple VDACS complying with the abovementioned description	0
ex 85.21 D II	Electronically adjustable differential amplifiers for at least the full range of signals from 0 to not less than 400 MHz in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 11 × 11 mm, with not more than 16 connecting pins, and bearing: — an identification marking consisting of or containing the following combination of figures: 0078-10 - or — other identification markings relating to amplifiers complying with the abovementioned description	0
ex 85.21 D II	Static, random-access memories of bipolar technology (bipolar SRAMs), in the form of a monolithic integrated circuit and with a storage capacity of 64 × 9 bits, contained in a housing the exterior dimensions of which do not exceed 16 × 40 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: 82 S 09 MBM 93419 - or — other identification markings relating to bipolar SRAMs complying with the abovementioned description	0
ex 85.21 D II	8 bit (octal) dynamic memory bipolar driver in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 16 × 33 mm, with not more than 20 connecting pins and bearing: — an identification marking consisting of or including one of the following combination of figures and letters: AM 2965 AM 2966 - or — other identification markings relating to dynamic memory bipolar drivers complying with the above description	0
ex 85.21 D II	Bus interface circuits of bipolar technology with 9 or 10 bit registers, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 9 × 34 mm, with not more than 24 connecting pins or contact areas and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking consisting of or including one of the following combinations of numbers and letters: AM 29821 AM 29843 AM 29823 AM 29844 AM 29824 or — other identification markings relating to BUS interface circuits which comply with the above description	0
ex 85.21 D II	Multiple bus interface circuit (Multiple Bus Buffer) of low power Schottky technology for interfacing the error correction and detection unit system data bus and dynamic random access memory (D-RAM), in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 8 × 33 mm, with not more than 24 connecting pins and bearing: — an identification marking consisting of or including the following combination of numbers and letters: AM 2961 or — other identification markings relating to error correction multiple bus buffers which comply with the above description	0
ex 85.21 D II	Status and shift control unit of bipolar technology in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 57 mm with not more than 42 connecting pins, and bearing: — an identification marking consisting of or including the following combination of figures and letters: AM 2904 or — other identification markings relating to status and shift control units complying with the above description	0
ex 85.21 D II	Amplifier, in the form of a monolithic integrated analog circuit the exterior dimensions of which do not exceed 3 × 3 mm for use in the manufacture of products falling within subheading 90.19 B I (a)	0
ex 85.21 D II	Text-co-processor, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins, and bearing: — an identification marking either consisting of or including the following combination of figures and letters: C 82730 or — other identification markings relating to text-co-processors complying with the above description	0
ex 85.21 D II	Single-chip-microcomputer, in the form of a monolithic integrated circuit, consisting of an arithmetic-logic unit with a capacity of 8 bits plus an electronic, programmable, read-only memory (EPROM) UV erasable with a capacity of 32 K bits and a random access memory (RAM) with a capacity of 1 K bit, contained in a housing the exterior dimensions of which do not exceed 15 × 50 mm, with a quartz window and not more than 40 connecting pins and bearing:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	— an identification marking either consisting of the following combination of figures or including this combination: 8751 7742 - or — other identification markings relating to single-chip-microcomputers which conform to the foregoing description	0
ex 85.21 D II	Single-chip microcomputers in C-MOS technology, in the form of a monolithic integrated circuit consisting of an ALU with a capacity of 32 bits plus a ROM with a capacity of 24 K bits and a RAM with a capacity of 2 K bits, contained in a housing the exterior dimensions of which are not less than 30 × 30 mm, with not less than 84 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: MB 8764 - or — other identification markings relating to single-chip microcomputers complying with the abovementioned description	0
ex 85.21 D II	Subscriber line audio-processing circuit (SLAC) with two digital signal processors, an analogue-digital converter and a digital-analogue converter, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: AM 7901 AM 7905 - or — other identification markings relating to SLACs complying with the abovementioned description	7
ex 85.21 D II	Monolithic integrated circuit in the form of pulse code modulation (PCM) of N-MOS (including H-MOS) technology, with encoding decoding and filter functions and a maximum data clock frequency of more than 3,5 MHz, contained in a housing the exterior dimensions of which do not exceed 8 × 26 mm, with not more than 20 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures: 2913 - or — other identification markings relating to integrated circuits complying with the abovementioned description	7
ex 85.21 D II	Non-volatile memory in the form of a monolithic integrated circuit, consisting of a C-MOS S-RAM, with a capacity of 16 K bits and internal power supply, contained in a housing the exterior dimensions of which do not exceed 17 × 33 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: MK 48 Z 02 (B) - or — other identification markings relating to non-volatile memories complying with the abovementioned description	7

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Subscriber line interface circuit (SLIC) with direct internal relay drive, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 18×39 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters: 5502 ICME 00155/RIFA (PBL) 3735 or — other identification markings relating to SLICs complying with the abovementioned description	0
ex 85.21 D II	Input output circuit of N-MOS (including H-MOS) technology for data control equipped with a timing control with a static random access memory (S-RAM) with a capacity of 128×8 bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16×54 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of one of the following combinations of figures or letters and figures or including one of those combinations: 6532 CO 10750 or — other identification markings relating to input output control circuits complying with the abovementioned description	0
ex 85.21 D II	4-channel drive circuit for stepping motor, of bipolar technology, with incorporated diodes, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 6×20 mm, with 16 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: HA 13007 75437 A or — other identification markings relating to motor drive circuits complying with the abovementioned description	0
ex 85.21 D II	Analog/digital monolithic integrated circuit used to control brushless motors, maintaining them at a constant speed, contained in a housing the exterior dimensions of which do not exceed 6×25 mm, with 18 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: MGA 3015 A or — other identification markings relating to integrated circuits complying with the abovementioned description	0
ex 85.21 D II	Analog/digital monolithic integrated circuit of bipolar technology for interface signals between the peripheral hard-disk memory unit and the central unit, contained in a housing the dimensions of which do not exceed 15×50 mm, with not more than 40 connecting pins, and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	— an identification marking consisting in or including the following combination of figures and letters: AD 581 C - or — other identification markings relating to integrated circuits complying with the abovementioned description	0
ex 85.21 D II	Voltage-multiplier circuit for operating stepping motors, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 6 × 24 mm, with not more than 20 connecting pins, and bearing: — an identification marking consisting of or including the following combination of figures and letters: P 20 A579 - or — other identification markings relating to voltage-multiplier circuits complying with the above description	0
ex 85.21 D II	Memory management unit of N-MOS (including H-MOS) technology (N-MOS MMU) with a maximum addressing capacity of 16 M bytes, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 25 × 82 mm, with not more than 64 connecting pins or 68 contact areas and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: 68451 L 6 68451 L 8 68451 L 10 68451 ZBL 6 68451 ZBL 8 68451 ZBL 10 TX 32082 W - or — other identification markings relating to N-MOS MMUs complying with the above description	0
ex 85.21 D II	Electronic circuit of advanced low power Schottky (ALPS) technology for the asynchronous control of signal lines (bus) and the conversion of a local bus into a multiplexed bus (BAM) in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 37 × 13 mm, with not more than 28 connecting pins and bearing: — the identification marking: 68452 - or — other identification markings relating to ALPS BAMs conforming to the foregoing description	0
ex 85.21 D II	Display controller and character generator (DCCG) for liquid crystal dot matrix display system in the form of a monolithic integrated circuit of C-MOS technology contained in a housing the exterior dimensions of which do not exceed 20 × 26 mm, with not more than 60 connecting pins, and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking consisting of the following combination of figures and letters: HD 61830 - or — other identification markings relating to C-MOS Display Controller and character generators complying with the abovementioned descriptions	0
ex 85.21 D II	Cathode-ray tube controller (CRTC) of N-MOS (including H-MOS) technology in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 62 × 25 mm, with not more than 68 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: AM 8052 D 8275 H P 8275 H - or — other identification markings relating to CRTCs complying with the abovementioned description	7
ex 85.21 D II	Video digital to analog converter (VDAC) with a maximum conversion time of 10 nanoseconds, in the form of a hybrid integrated circuit, contained in a housing the exterior dimensions of which do not exceed 20 × 35 mm, with not more than 24 connecting pins and bearing: — an identification marking consisting of or including one of the following combination of figures and letters: VDAC 0405 H VDAC 0605 H VDAC 0805 H - or — other identification markings relating to VDACS complying with the abovementioned description	0
ex 85.21 D II	Input/output management microprocessor of N-MOS (including H-MOS) technology in the form of a monolithic integrated circuit the exterior dimensions of which do not exceed 17 × 53 mm, with not more than 40 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: 8089 - or — other identification markings relating to input/output management microprocessors complying with the abovementioned description	0
ex 85.21 D II	Interpolation pulse generator of C-MOS technology for controlling geometrical functions, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: KM 3701 - or — other identification markings relating to interpolation modules complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Static, random access memory of C-MOS technology (C-MOS S-RAM) with a storage capacity of 32 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 18 × 39 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: TC 5532 or — other identifying marking relating to C-MOS S-RAM complying with the abovementioned description	0
ex 85.21 D II	Controller for servo-devices of C-MOS technology in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17 × 54 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: KM 3702 or — other identification markings relating to controllers complying with the abovementioned description	0
ex 85.21 D II	Function generator of bipolar technology for the generation of variable waveforms, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 10 × 21 mm, with not more than 16 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: XR 2206 XR 8038 or — other identification markings relating to function generators complying with the abovementioned description	0
ex 85.21 D II	Video amplifier of bipolar technology in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 17 mm, with not more than 44 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 702 703 or — other identification markings relating to video amplifiers complying with the abovementioned description for use in the manufacture of portable colour television cameras (a)	0
ex 85.21 D II	Amplifier, of bipolar technology for the amplification of either read or write signals of floppy discs, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 11 × 29 mm, with not more than 22 connecting pins and bearing:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking consisting of or including one of the following combinations of figures and letters: XR 2247 XR 3470 or — other identification markings relating to amplifiers complying with the abovementioned description	0
ex 85.21 D II	Aperture and colour temperature balance controller of bipolar technology, in the form of a monolithic integrated analog circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 17 mm, with not more than 44 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures: 704 or — other identification markings relating to devices complying with the abovementioned description for use in the manufacture of portable colour television cameras (a)	0
ex 85.21 D II	Impulse generator in C-MOS technology, in the form of a monolithic integrated digital circuit, contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins and bearing: — an identification marking consisting of or including one of the following combination of figures: 705 706 or — other identification markings relating to impulse generators complying with the abovementioned description for use in the manufacture of portable colour television cameras (a)	0
ex 85.21 D II	Static random access memories of bipolar technology (bipolar S-RAMs) in the form of a monolithic integrated circuit consisting of a substrate layer on which are mounted either 1 or 2 chips each having a storage capacity of 1 K bit, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 23 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures: 770639 770823 5120360 7379769 or — other identification markings relating to bipolar S-RAMs complying with the abovementioned description	0
ex 85.21 D II	Static memories consisting of two stacked substrate layers with one or two static random access memories of bipolar technology (bipolar S-RAMs) in the form of monolithic integrated circuits, each with a storage capacity of 1 K bits and with a maximum storage capacity of 4 K bits, contained in a housing the exterior dimensions of which do not exceed 13 × 13 mm, with not more than 23 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 770965 4599497 7379442 or — other identification markings relating to static memories complying with the abovementioned description	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Programmable digital signal synthesizer of C-MOS technology with 32 frequency generators to generate 8 notes each and a simultaneous output of up to 160 notes in the form of a monolithic integrated circuit contained in a housing, the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins or contact areas. The housing bears: — an identification marking either consisting of or including the following combination of letters: MEG - or — other identification markings relating to digital synthesizers complying with the abovementioned description	0
ex 85.21 D II	Repeater circuit, of bipolar technology for the regeneration of pulse code-modulated signals, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 10 × 21 mm, with not more than 16 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: XR C 240 - or — other identification markings relating to repeater circuits complying with the abovementioned description	0
ex 85.21 D II	Dynamic random access memory controller of N-MOS (including H-MOS) technology (N-MOS D-RAM controller) capable of multiplexing addresses and generating timing, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17 × 62 mm, with not more than 48 connecting pins or 52 contact areas, and bearing: — an identification marking consisting of or including the following combination of figures and letters: C 8208 THCT 4502 - or — other identification markings relating to N-MOS D-RAM controllers complying with the abovementioned description	0
ex 85.21 D II	C-MOS clock/calendar circuit, incorporating a quartz crystal oscillator, independent timer recorders and a timer, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 7 × 20 mm with not more than 16 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: MM 58174 A 58274 - or — other identification markings relating to clock/calendar circuits complying with the abovementioned description	0
ex 85.21 D II	Programmable asynchronous communication element circuit in N-MOS technology, for the asynchronous transmission and reception of data, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 16 × 54 mm, with not more than 40 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking either consisting of or including the following combination of figures and letters: INS 8250 NS 16450 WD 8250 NS 16 C 450 - or — other identification markings relating to ACE circuits complying with the abovementioned description	0
ex 85.21 D II	Dynamic, random-access read/write memory of N-MOS (including H-MOS) technology, (N-MOS D-RAMs) with a storage capacity of 64 K × 4 bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 17 × 34 mm, with not more than 20 connecting pins or contact areas arranged in two parallel lines (dual-in-line package) and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters TMS 4464 PD 41254 PD 41464 TMM 41464 M5M 4464 HM 50464 MB 81464 - or — other identification markings relating to N-MOS D-RAMs complying with the abovementioned description	10
ex 85.21 D II	Encoder/decoder circuit using Manchester code (MED) for the transmission of data in continuous flux with a repeater mode in C-MOS technology, having an output voltage of 4,5 volts, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 16 × 33 mm, with not more than 20 connecting pins and bearing: — an identification marking consisting or including the following combination of figures and letters: HD 6409 - or — other identification markings relating to circuits complying with the abovementioned description	0
ex 85.21 D II	UV-erasable programmable read-only memories (EPROMs) in the form of a monolithic integrated circuit with a storage capacity of 512 K bits, contained in a housing the exterior dimensions of which do not exceed 20 × 42 mm, with a quartz window on the upper surface. The housing bears: — an identification marking consisting or including the following combination of figures and letters: AM 27512 - or — other identification markings relating to EPROMs complying with the abovementioned description	0
ex 85.21 D II	TTL Logic modules in bipolar technology with not more than six logic functions in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 17 × 34 mm, with not more than 24 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures or letters: SH 767 369 SH 998 088 - or — another identification marking relating to logic modules as described above	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Control and interface circuit for central processor (CPU-Controller) of C-MOS technology in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 25 × 25 mm, with not more than 68 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of letters and figures: FE 2000 L1A0392 or — other identification markings relating to control and interfacing circuits complying with the abovementioned description	0
ex 85.21 D II	Circuit for the control of floppy discs (floppy disc controller) of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 16 × 62 mm, with not more than 48 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of letters and figures: FE 2100 G 70360-33 MB 89311 or — other identification markings relating to adaptor circuits complying with the abovementioned description	7
ex 85.21 D II	Pulse code modulation (PCM) Codec and filter of NMOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of a fully integrated PCM Codec with transmit/receive filters, contained in a housing the exterior dimensions of which do not exceed 10 × 23 mm, with not more than 16 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: 2916 2917 or — either identification markings relating to PCM Codec and filter devices complying with the abovementioned description	7
ex 85.21 D II	6-Channel monolithic integrated circuit (Read/write data processor circuit) for the amplification and conversion of read signals and conversion of write signals for hard disc drives, contained in a housing the exterior dimensions of which do not exceed 19 × 38 mm, with not more than 28 connecting pins or contact areas and bearing: — an identification marking consisting of or including the following combination of letters and figures: SSI 540 or — other identification markings relating to integrated circuits complying with the abovementioned description	0
ex 85.21 D II	8-Channel control circuit for maintaining a constant electromagnetic traction force with incorporated diodes and a storage capacity of 8 bits, in the form of a monolithic integrated circuit, of C-MOS technology contained in a housing the exterior dimensions of which do not exceed 9 × 28 mm, with not more than 22 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	— an identification marking either consisting of or including the following combination of figures and letters: UCN 5801 or — other identification markings relating to control circuits complying with the abovementioned description	0
ex 85.21 D II	4-Channel control circuit for maintaining a constant electro magnetic traction force with incorporated diodes and a storage capacity of 4 bits, in the form of a monolithic integrated circuit of C-MOS technology, contained in a housing the exterior dimensions of which do not exceed 7×22 mm, with not more than 16 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: UCN 5813 or — other identification markings relating to control circuits complying with the abovementioned description	0
ex 85.21 D II	Monolithic integrated circuit for scanning and distributing logic signals, for use in telephone exchanges, contained in a housing the exterior dimensions of which do not exceed 14×53 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: QMV 16 BW 1 or — other identification markings relating to integrated circuits complying with the abovementioned description	7
ex 85.21 D II	Monolithic integrated interface circuit for pulse code modulation (PCM), of C-MOS technology, with encoding, decoding and filtering functions and a processing frequency of 2,565 MHz, contained in a housing the exterior dimensions of which do not exceed 10×28 mm, with not more than 22 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: QMV 81 AD 1 or — other identification markings relating to integrated circuits complying with the abovementioned description	7
ex 85.21 D II	Six-channel monolithic integrated circuit for the generation of read/write signals for hard disc drives, contained in a housing the exterior dimensions of which do not exceed 13×13 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of letters and figures: SSI 117 or — other identification markings relating to integrated circuits complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Programmable non-erasable read-only memories (PROMS) with a storage capacity of 16 K bits, in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 39 × 17 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: 27 PS 191 A 7 C 245 7 C 292 29683 7 C 291 HM 6616 - or — other identification markings relating to PROMS complying with the abovementioned description	0
ex 85.21 D II	Amplifiers for a full range of signals from 0 to 60 KHz in the form of a monolithic integrated circuit contained in a housing the exterior dimensions of which do not exceed 6 × 13 × 26 mm, with not more than 18 connecting pins and a leakage of not more than 0,3µA and bearing: — an identification marking either consisting of or including the following combination of figures and letters: ISO 100 - or — other identification markings relating to amplifiers complying with the abovementioned description, for use in the manufacture of telephone exchanges (a)	0
ex 85.21 D II	Light-emitting diode (LED) made from a gallium-based semiconductor compound contained in a housing the exterior dimensions of which do not exceed 20 × 21 mm, with 2 connecting pins and bearing: — an identification marking consisting of or including one of the following identification markings: LT 9305 LT 9306 SLF 209 SLF 909 - or — other identification markings relating to LEDs, complying with the abovementioned description	0
ex 85.21 D II	Single chip microcomputer of C-MOS technology, in the form of a monolithic integrated circuit, consisting of an arithmetical logic unit (ALU) with an organization of 4 bits, a read-only memory (ROM) with a storage capacity of 2 K × 8 bits, a dual-tone, multi-frequency (DTMF) generator, a random access memory (RAM) with a storage capacity of 1 K bit, whether or not with another random access memory (RAM) with a storage capacity of 512 bits, contained in a housing whose exterior dimensions do not exceed 16 × 54 mm, with not more than 42 connecting pins and bearing: — an identification marking consisting of one of the following combination of figures and letters: T 6978 TCM 8301 TCM 8302 - or — other identification markings relating to single chip microcomputers complying with the abovementioned description	0
ex 85.21 D II	Asynchronous first-in first-out (FIFO) memories of C-MOS technology in the form of a monolithic integrated circuit with a capacity of 64 × 4 bits, or 64 × 5 bits, contained in a housing the exterior dimensions of which do not exceed 11 × 24 mm with not more than 18 connecting pins and bearing:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking either consisting of or including one of the following combinations of figures or figures and letters: CY7C401 CY7C402 CY7C403 CY7C404 CY 3341 or — other identification markings relating to asynchronous first-in first-out memories complying with the abovementioned description	0
ex 85.21 D II	Static random access memories of C-MOS technology (C-MOS S-RAMs) in the form of a monolithic integrated circuit with a storage capacity of 16×4 bits, an access time not exceeding 35 ns, contained in a housing the exterior dimensions of which do not exceed 9×21 mm, with not more than 16 connecting pins and bearing: — an identification marking either consisting of or containing one of the following combinations of figures and letters: CY7C189 CY7C190 CY74S189 CY54S189 CY27S03 C727S07 or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	0
ex 85.21 D II	Static random access memories of C-MOS technology (C-MOS S-RAMs) in the form of a monolithic integrated circuit with a storage capacity of 256×4 bits and an access time not exceeding 60 ns, contained in a housing the exterior dimensions of which do not exceed 12×29 mm, with not more than 22 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures or figures and letters: CY7C122 CY93422/93L422 or — other identification markings relating to C-MOS S-RAMs complying with the abovementioned description	0
ex 85.21 D II	Electrically erasable, programmable read-only memories (so-called E² PROMs), in the form of an unmounted monolithic integrated circuit (chip) with a storage capacity of 16 K bits, used in the manufacture of microwave systems for the identification of persons and objects (a)	0
ex 85.21 D II	Dynamic read/write random access memories manufactured in N-MOS (including H-MOS) technology (so-called dynamic N/H-MOS-RAMs), in the form of a monolithic integrated circuit, consisting of a substrate layer with not less than two and not more than eight chips having a storage capacity of 128, 192 or 256 K bits and a storage capacity of not less than 256 K bits and not more than 2 megabits, contained in a housing whose dimensions do not exceed 30×30 mm, with not more than 57 connecting pins and bearing:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)																
ex 85.21 D II (cont'd)	— an identification marking either consisting of or including one of the following combinations of figures: <table><tr><td>6025841</td><td>6031587</td><td>6870392</td><td>7379172</td></tr><tr><td>6025843</td><td>6031591</td><td>6870393</td><td>7379174</td></tr><tr><td>6025856</td><td></td><td>6870395</td><td>7379176</td></tr><tr><td>6025858</td><td></td><td></td><td>7379181</td></tr></table> or — other identification markings relating to dynamic read/write memories of the type described above	6025841	6031587	6870392	7379172	6025843	6031591	6870393	7379174	6025856		6870395	7379176	6025858			7379181	0
6025841	6031587	6870392	7379172															
6025843	6031591	6870393	7379174															
6025856		6870395	7379176															
6025858			7379181															
ex 85.21 D II	Dual Port Dynamic Random Access Memory (D-RAM) of N-MOS (including H-MOS) technology, with data registers and a serial read output control, with a storage capacity of 256 K bits in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 13 × 39 mm, with not more than 24 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures: MB 81461 PD 41264 or — other identification markings relating to D-RAMs complying with the abovementioned description	0																
ex 85.21 D II	Bus interface circuit in C-MOS technology, in the form of a monolithic integrated circuit, for the control of communication lines comprising a numerical bus, two independent receivers and a transmitter consisting of a first-in first-out (FIFO) memory contained in a housing whose exterior dimensions do not exceed 15 × 50 mm with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: HS 3282 or — other identification markings relating to bus interface circuits and corresponding to the abovementioned description	0																
ex 85.21 D II	Monolithic integrated circuit in N-MOS technology (including H-MOS) for the display of graphic symbols on a cathode-ray tube operating in stroke mode, contained in a housing whose exterior dimensions do not exceed 28 × 61 mm, with not more than 68 connecting pins and bearing: — an identification marking consisting of or including the following combinations of figures and letters: FCD 28 042 277, 96 114 899, 96 149 135, 96 114 898 or — other identification markings relating to circuits corresponding to the abovementioned description	0																
ex 85.21 D II	Random access memories of ECL technology (ECL-RAMs) with a storage capacity of 256 × 4 bits, and access time not exceeding 8 ns in the form of a monolithic integrated circuit, contained in a housing the dimensions of which do not exceed 11 × 32 mm, with not more than 24 connecting pins and bearing:																	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (<i>cont'd</i>)	— an identification marking either consisting of or including the following combination of figures: 10422 10422 A - or — other identification markings relating to ECL-RAMs complying with the abovementioned description	0
ex 85.21 D II	Static, random access memories (S-RAMs) of C-MOS technology, with a storage capacity of 256 K bits, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 39 × 17 mm, with not more than 28 connecting pins and bearing: — an identification marking either consisting of or including one of the following combinations of figures and letters: HM 62256 PD 43256 C TC 55257 P - or — other identification markings relating to S-RAMs complying with the abovementioned description	0
ex 85.21 D II	Random access memories of ECL technology (ECL-RAMs) with a storage capacity of 16 K bits, in the form of a monolithic integrated circuit, contained in a housing the dimensions of which do not exceed 9 × 27 mm, with not more than 20 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures: 10480 - or — other identification markings relating to ECL-RAMs complying with the abovementioned description	0
ex 85.21 D II	Octal Line Driver of Schottky-TTL technology in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 14 × 14 mm, with not more than 28 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: 5170 NE 5170 UC 5170 - or — other identification markings relating to Octal Line Drivers complying with the abovementioned description	0
ex 85.21 D II	Octal Line Receiver of Schottky-TTL technology in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 14 × 14 mm, with not more than 28 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: 5180 NE 5180 5181 NE 5181 8510 8511 - or — other identification markings relating to Octal Line Receivers complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Interface circuit for the synchronization of data flow from a hard disk drive, in the form of a monolithic integrated circuit, contained in a housing whose dimensions do not exceed 16 × 35 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: DP 8462 - or — other identification markings relating to interfaces complying with the abovementioned description	0
ex 85.21 D II	Hard Disc Data Separator (HDDS) in the form of a monolithic integrated circuit, contained in a housing whose exterior dimensions do not exceed 16 × 37 mm, with not more than 28 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: DP 8460-2 DP 8460-3 DP 8460-4 DP 8465 WD 10C20 - or — other identification markings relating to devices complying with the abovementioned description	0
ex 85.21 D II	Hybrid integrated circuit for electromagnet control consisting of 4 Darling-ton pairs (1 Darling-ton = 2 transistors with a cascade connection) contained in a housing having exterior dimensions which do not exceed 12 × 27 mm with not more than 10 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: TH 3L10 - or — other identification markings relating to integrated circuits complying with the abovementioned description	0
ex 85.21 D II	Interface circuit of C-MOS technology for signals between peripheral hard disc memory unit and central unit in the form of a monolithic integrated circuit contained in a housing whose exterior dimensions do not exceed 28 × 53 mm with not more than 68 connecting pins or contact areas and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: OMTI 508 AIC 500 OMTI 509 AIC 16000 WD 11C00 - or — other identification markings relating to interface circuits complying with the abovementioned description	0
ex 85.21 D II	Sequential data control circuit of MOS technology for interface between a hard disc memory unit and the memory control unit in the form of a monolithic integrated circuit of MOS technology contained in a housing whose exterior dimensions do not exceed 28 × 28 mm, with not more than 68 connecting pins and bearing:	

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II (cont'd)	— an identification marking consisting of or including one of the following combinations of figures and letters: AIC 010 OMTI 5050 or — other identification markings relating to sequential circuits complying with the abovementioned description	0
ex 85.21 D II	Encoder/decoder serial interface circuit for hard disc drives, in the form of a monolithic integrated circuit contained in a housing whose exterior dimensions do not exceed 17 × 37 mm with not more than 28 connecting pins and bearing: — an identification marking consisting of or including one of the following combinations of figures and letters: OMTI 5070 AIC 250 OMTI 5027 AIC 270 or — other identification markings relating to interface circuits complying with the abovementioned description	0
ex 85.21 D II	Electronic control circuit for static memory control (S/RAM) with address multiplexing and pulse generation facility, in the form of a monolithic integrated circuit of MOS technology contained in a housing whose dimensions do not exceed 28 × 28 mm, with not more than 68 connecting pins or contact areas and bearing: — an identification marking consisting of or including one of the following combination of figures and letters: OMTI 506 AIC 300 or — other identification markings relating to electronic control circuits complying with the abovementioned description	0
ex 85.21 D II	Pulse code modulation (PCM) codec of N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of a sample and hold circuit digital to analogue converter, comparator, successive approximation register and logic function to interface to a full duplex PCM link, contained in a housing whose exterior dimensions do not exceed 11 × 28 mm, with not more than 22 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: 2911 A-1 or — other identification markings relating to PCM Codecs complying with the abovementioned description	7
ex 85.21 D II	Pulse code modulation (PCM) transmit/receive filter of N-MOS (including H-MOS) technology, in the form of a monolithic integrated circuit, consisting of two filters of a PCM line or trunk termination, contained in a housing whose exterior dimensions do not exceed 10 × 21 mm, with not more than 16 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: 2912 A or — other identification markings relating to PCM filters complying with the abovementioned description	7

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 D II	Dynamic random access memories of C-MOS technology (C-MOS D-RAMs) with a storage capacity of 256 K bits in the form of a monolithic integrated circuit, contained in a housing whose external dimensions do not exceed 17 × 34 mm, with not more than 18 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures and letters: P 51 C 256 P 51 C 259 or — other identification markings relating to C-MOS D-RAMs complying with the abovementioned description	0
ex 85.21 D II	Cathode ray tube controller (CRTC) of bipolar technology in the form of a monolithic integrated circuit contained in a housing whose exterior dimensions do not exceed 15 × 55 mm with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: SCB 2675 or — other identification markings relating to CRTCs complying with the abovementioned description	0
ex 85.21 D II	Programmable non-erasable read-only memories (PROMs) with a storage capacity of 32 K bits, in the form of a monolithic integrated circuit, whose external dimensions do not exceed 17 × 39 mm, with not more than 32 connecting pins or contact areas and bearing: — an identification marking either consisting of or including the following combination of figures and letters: 63S3281 AM 27S43 or — other identification markings relating to PROMs complying with the abovementioned description	0
ex 85.21 D II	Programmable advanced video display controllers (AVDCs) of N-MOS (including H-MOS) technology in the form of a monolithic integrated circuit, contained in a housing whose external dimensions do not exceed 15 × 55 mm, with not more than 40 connecting pins and bearing: — an identification marking either consisting of or including the following combination of figures and letters: SCN 2674 or — other identification markings relating to controllers complying with the abovementioned description	7
ex 85.21 D II	Control circuit of TTL-technology in the form of a monolithic integrated circuit for the firing of magnetic print hammers, contained in a housing the exterior dimensions of which do not exceed 7 × 20 mm with not more than 16 connecting pins and bearing: — an identification marking consisting of or including the following combination of figures: 801379-002 or — other identification markings relating to integrated circuits complying with the abovementioned description	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 85.21 E	Deflector yoke for cathode ray tubes with an operating frequency of between 31 250 Hz and 64 000 Hz incorporating a quadripolar magnet	0
ex 85.23 B	Insulated winding wire of aluminium of a purity of not less than 99,5 % by weight, neither lacquered, varnished nor enamelled, with a total thickness of not less than 0,15 mm and not more than 0,16 mm	0
ex 90.02 B	Image reversers made up from an assembly of optical fibres	0
ex 90.02 B	Adjustable lens unit, having a focal length of between 115 mm and 140 mm, a diameter of not less than 120 mm and not more than 130 mm, and comprising a combination of between four and eight glass or methacrylic lenses, each lens coated on at least one side with a magnesium fluoride layer, for use in the manufacture of video projectors (a)	0
ex 90.02 B	Element, consisting of two rows of rigid optical filaments mounted between two plastic plates, whose maximum external dimensions do not exceed $276 \times 20 \times 5$ mm, not fitted with cables or connectors, for use in the manufacture of photocopiers (a)	0
ex 90.10 A	Optical unit for photocopiers consisting of two rows of rigid optical monofilament fibres between two plates of plastic material, a tube lamp and a metal reflector, mounted on a metal structure whose maximum dimensions do not exceed $335 \times 100 \times 40$ mm	0
ex 90.10 A	Unit for photocopier, not fitted with an optical fibre assembly, consisting of a halogen lamp and metal reflector mounted in a metal structure whose maximum dimensions (without taking account of cables and connectors) do not exceed $290 \times 112 \times 53$ mm	0
ex 90.19 B II	Portable reading appliance for the visually handicapped in which a fibre optic camera transmits a magnified image on to a display screen, and parts thereof	3

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

TABLE II

CCT heading No	Description	Rate of autonomous duty (%)
ex 27.07 A I	Crude light oils containing by weight: — not less than 10 % of vinyltoluenes — not less than 10 % of indene — not less than 1 % and not more than 5 % of naphthalene	0
ex 27.10 B III	Mixture of hydrocarbons, consisting of 85 % or more of linear paraffins by weight, with chain lengths of eight to 16 carbon atoms, and of not more than 13 % of alkylbenzenes by weight, with linear chains of 10 to 12 carbon atoms	0
ex 27.13 B II	1-Alkenes containing a C 18 to C 30 carbon chains	0
ex 28.04 B	Helium	0
ex 28.05 C I	Alloys of cerium and other rare earth metals containing not less than 47 % by weight of cerium	0
ex 28.13 IJ	Tellurium dioxide	0
ex 28.14 B	Iodine pentafluoride	0
ex 28.21	Chromium dioxide	0
ex 28.22 B	Manganese oxide containing not less than 77 % by weight of manganese	0
ex 28.39 A	Potassium nitrite for the manufacture of cooling and cutting fluids used in the working of metal or metal carbides (a)	0
ex 28.40 B II	<i>penta</i> Calcium hydroxide tris(orthophosphate) for use in non-ferrous metallurgy (a)	0
ex 28.42 A VI	Lithium carbonates not corresponding to the following specifications in the form of white powder, containing 98,5 % or more of Li_2CO_3 and: — less than 2 ppm of arsenic — less than 200 ppm of calcium — less than 200 ppm of chlorides — less than 20 ppm of iron — less than 150 ppm of magnesium — less than 20 ppm of heavy metals — less than 300 ppm of potassium — less than 300 ppm of sodium — less than 200 ppm of sulphates	0
28.46 A I b)	Sodium borate, anhydrous	0
ex 28.46 A II	Disodium tetraborate pentahydrate	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 28.47 F	Calcium wolframate, for the manufacture of ferro-alloys or decaammonium 41-oxododecawolframate (ammonium paratungstate) (a)	0
ex 28.48 B III	Hydrotalcite (INN)	0
ex 28.49 C II and/or ex 30.03 A II b)	Carboplatin (INN)	0
28.51 A	Deuterium, deuterium oxide (heavy water) and other compounds of deuterium; hydrogen and compounds thereof enriched in deuterium, mixtures and solutions containing these products (<i>Euratom</i>)	0
ex 29.01 C I	<i>beta</i> -Pinene	0
ex 29.01 D VII	Vinyltoluenes	0
ex 29.01 D VII	Tricyclo [8.2.2.2. ^{4,7}] hexadeca-1(12),4,6,10,13,15-hexaene	0
ex 29.01 D VII	<i>p</i> -Cymene	0
ex 29.02 A I	Carbon tetrafluoride (tetrafluoromethane)	0
ex 29.02 A III	Vinyl bromide	0
ex 29.02 A III	1,2-Dibromoethane	4
ex 29.02 A V	Bromochloromethane	0
ex 29.02 B	1,6,7,8,9,14,15,16,17,17,18,18-Dodecachloropentacyclo [12.2.1.1. ^{6,9} .0 ^{2,13} .0 ^{5,10}]octadeca-7,15-diene, for use in the manufacture of polyamide (a)	0
ex 29.02 C	Di- or tetrachlorotricyclo [8.2.2.2. ^{4,7}] hexadeca-1(12),4,6,10,13,15-hexaene, mixed isomers	0
ex 29.03 A	Methanesulphonic acid	0
ex 29.03 B II	Nitromethane	0
ex 29.03 B II	1-Nitropropane	0
ex 29.03 B II	2-Nitropropane	0
ex 29.03 B II	Nitroethane	0
ex 29.03 C I	Methanesulphonyl chloride	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.03 C I	2,2,2-Trifluoroethyl trichloromethanesulphonate	0
ex 29.04 C I	Butane-1,3-diol	0
ex 29.04 C I	2,4,7,9-Tetramethyldec-5-yne-4,7-diol	0
ex 29.04 C I	Hexane-1,6-diol	0
ex 29.04 C V	2,2-Bis(bromomethyl)propanediol	0
29.05 A II	Menthol	0
ex 29.05 A IV	Labd-14-ene-8,13-diol	0
ex 29.06 A IV	2-Isopropylphenol	0
ex 29.06 B V	4,4'-(2,3-Dimethyltetramethylene)dipyrocatechol, not less than 98 % pure	0
ex 29.06 B V	6,6',6''-Tri- <i>tert</i> -butyl-4,4',4''-(1-methylpropan-1-yl-3-ylidene)tri- <i>m</i> -cresol, whether or not containing toluene of crystallization	0
ex 29.06 B V	2,5-Di-(<i>tert</i> -pentyl) hydroquinone	0
ex 29.07 A	4,4'-(Perfluoroisopropylidene)diphenol	0
ex 29.07 C III	2,4-Dinitro-6-octylphenol	0
ex 29.08 A III c)	2-Bromo-6-methoxynaphthalene	0
ex 29.08 A III c)	Bis (phenoxyphenoxy) benzene, mixed isomers	0
ex 29.08 A III c)	1,2-Bis (2,4,6-tribromophenoxy) ethane for use in the manufacture of acrylonitrile-butadiene-styrene (ABS) (a)	0
ex 29.08 B I	3,3'-Oxydi(propylene glycol)	0
ex 29.08 B I	2-(2-Chloroethoxy)ethanol	0
ex 29.08 B II	2,2'-[Isopropylidenebis(2,6-dibromo-4,1-phenyleneoxy)]diethanol	0
ex 29.13 A I	5-Methylhexan-2-one	0
ex 29.13 A I	3,3-Dimethylbutanone	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.13 B I b)	Refined natural bornan-2-one(camphor)	0
ex 29.13 D I b)	11- <i>alpha</i> ,17,21-Trihydroxy-16- <i>beta</i> -methylpregna-1,4-diene-3,20-dione	0
ex 29.13 E	4-Methoxy-4-methylpentan-2-one	0
ex 29.13 E	6' -Methoxy-2' -propiononaphthone	0
ex 29.13 F	1,4-Naphthoquinone	0
ex 29.13 F	Ubidecarenone (INN) (Coenzyme Q-10)	0
ex 29.13 G II	1-Chloro-3,3-dimethylbutanone	0
ex 29.14 A II c) 4	20-Oxopregna-5,16-dien-3- <i>beta</i> -yl acetate	0
ex 29.14 A VII	1-Isopropyl-2,2-dimethyltrimethylene diisobutyrate	0
ex 29.14 B IV b)	Methacryloyl chloride	0
ex 29.14 B IV b)	Butyl perchlorocrotonate	0
ex 29.15 A IV a)	Azelaic acid and sebacic acid	0
ex 29.15 A V	Sodium 1,2-bis(cyclohexyloxycarbonyl)ethanesulphonate	0
ex 29.15 C III	Benzene-1,2,4-tricarboxylic acid	0
ex 29.15 C III	Benzene-1,2,4-tricarboxylic acid 1,2-anhydride	0
ex 29.15 C III	Tetrachlorophthalic anhydride	0
ex 29.15 C III	Tetrabromophthalic anhydride	0
ex 29.15 C III	Benzene-1,2,4-tricarbonyl trichloride	0
ex 29.16 A II	Malic acid and its salts, with an <i>L</i> -isomer of not less than 94 %	0
ex 29.16 A VIII a)	2,2-Bis(hydroxymethyl)propionic acid	0
ex 29.16 B VI	Octadecyl-3-(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl)propionate	0
ex 29.16 B VI	Pentaerythritol tetrakis[3-(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl)propionate]	0
ex 29.16 D	Dinoprostone (INN)	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.16 D	Alprostadil (INN)	0
ex 29.16 D	2,6-Dimethoxybenzoic acid	0
ex 29.19 C	2,2-Bis(chloromethyl)trimethylene tetrakis(2-chloroethyl) bis(phosphate)	5
ex 29.21 A	Diethyl sulphate	0
ex 29.21 B II	0,0'-Bis(2,4-di- <i>tert</i> -butylphenyl) pentaerythritol bis(phosphite)	0
ex 29.21 B II	0,0' -Dioctadecyl pentaerythritol bis (phosphite)	0
ex 29.22 A III	<i>tert</i> -Butylamine	0
ex 29.22 A III	1,1,3,3-Tetramethylbutylamine	0
ex 29.22 B II	<i>N,N,N',N'</i> -Tetrabutylhexamethylenediamine	0
ex 29.22 C II	Cyclohex-1,3-ylenediamine (1,3-diaminocyclohexane)	0
ex 29.22 D IV	<i>alpha',alpha',alpha'</i> -Trifluoro-2,3-xylidine	0
ex 29.22 E II	<i>m</i> -Phenylenebis(methylamine)	0
ex 29.22 E II	1,8-Naphthylenediamine	0
ex 29.23 A II	Dinoprost (INN), Trometamol (INN) salt	0
ex 29.23 A II	(+)-4-Dimethylamino-3-methyl-1,2-diphenylbutan-2-ol	0
ex 29.23 A II	1-Deoxy-1-(octylamino)- <i>D</i> -glucitol	0
ex 29.23 B II	Dobutamine (INN) and its salts	0
ex 29.23 C and/or ex 30.03 A II B)	Ketamine hydrochloride (INN)	0
ex 29.23 D V	Tranexamic acid (INN)	0
ex 29.23 D V	<i>beta</i> -Alanine	0
ex 29.23 E	Metipranolol (INN)	0
ex 29.23 E	Diethyl-1,3-benzodioxol-5-ylaminomethylenemalonate	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.23 E	Levodopa (INN)	0
ex 29.23 E	Nadolol (INN)	0
ex 29.23 E	Methyldopa (INN)	0
ex 29.23 E	Indenolol hydrochloride (INNM)	0
ex 29.23 E	Glucosamine hydrochloride (INNM)	0
ex 29.25 A II	(3-Methacrylamidopropyl)trimethylammonium chloride	0
ex 29.25 A II	2-Acrylamido-2-methylpropanesulphonic acid and its sodium or ammonium salts	0
29.25 B II a)	Phenobarbital (INN) and its salts	11
ex 29.25 B III b)	Bendiocarb (ISO)	0
ex 29.25 B III b)	Flutamide (INN)	0
ex 29.26 A II	3,3',4,4',5,5',6,6'-Octabromo- <i>N,N'</i> -ethylenedipthalimide	0
ex 29.27	(—)- <i>N</i> -(<i>alpha</i> -Cyano-4-hydroxy-3-methoxy- <i>alpha</i> -methylphenethyl)acetamide	0
ex 29.27	2-(3-Phenoxyphenyl)propiononitrile	0
ex 29.27	Isophthalonitrile	6
ex 29.29	20-Hydroxyiminopregna-5,16-dien-3-yl acetate	0
ex 29.29	Carbidopa (INN)	0
ex 29.29	Robenidine hydrochloride (INNM)	0
ex 29.29	<i>N,N</i> -Diethylhydroxylamine	0
ex 29.29	3,3'-Bis(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl) <i>N,N'</i> -bipropionamide	0
ex 29.29	2,4,6-Trichlorophenylhydrazine	0
ex 29.30	0,0-Bis(4- <i>tert</i> -butylphenyl)- <i>N</i> -cyclohexylphosphoramidothioate	0
ex 29.30	Methylenedicyclohexyl di-isocyanate, mixed isomers	0
ex 29.30	<i>p</i> -Phenylene diisocyanate	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.30	<i>trans</i> -(Cyclohex-1,4-ylene diisocyanate) for the production of thermoplastic polyurethane elastomers (a)	0
ex 29.30	3,3-Dimethylbiphenyl-4,4-diyl diisocyanate	0
ex 29.31 B	Thiophenol	0
ex 29.31 B	2,2'-Thiodiethyl bis[3-(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl)propionate]	0
ex 29.31 B	Probucol (INN)	0
ex 29.31 B	Ethoprophos (ISO)	0
ex 29.31 B	Cilastatin sodium (INN)	0
ex 29.34 C	Crystalline dimethyltin dichloride in the form of powder, for the production of goods falling within Chapter 70 (a)	0
ex 29.34 C	2-Chloroethylphosphonic acid	3,8
ex 29.34 C	Chlorodiphenylphosphine	0
ex 29.34 C	2-Diphenylphosphinobenzoic acid	0
ex 29.35 Q	Octrizole (INN)	0
ex 29.35 Q	Drometrizole (INN)	0
ex 29.35 Q	2,6-Di- <i>tert</i> -butyl-4-[4,6-bis(octylthio)-1,3,5-triazin-2-yl-amino]phenol	0
ex 29.35 Q	Timolol (INN)	0
ex 29.35 Q	Clotiazepam (INN)	0
ex 29.35 Q	1,4-Diazabicyclo[2.2.2]octane (triethylenediamine)	0
ex 29.35 Q	2,4-Di- <i>tert</i> -butyl-6-(5-chlorobenzotriazol-2-yl)phenol	0
ex 29.35 Q	Carpipramine dihydrochloride (INN)	0
ex 29.35 Q	2,3-Dihydro-2,2-dimethylbenzofuran-7-ol	0
ex 29.35 Q	1-Ethyl-1,4-dihydro-4-oxo[1,3]dioxolo[4,5- <i>g</i>]cinnoline-3-carbonitrile	0
ex 29.35 Q	Diphepanil metilsulphate (INN)	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.35 Q	(25 R)-Spirost-5-en-3- <i>beta</i> -ol (diosgenin) and its esters	0
ex 29.35 Q	Azatadine dimaleate (INN ^M)	0
ex 29.35 Q	Amprolium-hydrochloride (INN ^M)	0
ex 29.35 Q	2-(4-Pyridyl)ethanesulphonic acid	0
ex 29.35 Q	Prifinium bromide (INN)	0
ex 29.35 Q	Glucurrolactone (INN)	0
ex 29.35 Q	2-Chlorodibenz[<i>b,f</i>][1,4]oxazepin-11(10 <i>H</i>)-one	0
ex 29.35 Q	2,3,5,6-Tetrachloropyridine	0
ex 29.35 Q	Diltiazem hydrochloride (INN ^M)	0
ex 29.35 Q	(6 <i>R</i> ,7 <i>R</i>)-3-Acetoxymethyl-7-[(<i>R</i>)-2-formyloxy-2-phenylacetamido]-8-oxo-5-thia-1-azabicyclo[4.2.0]oct-2-ene-2-carboxylic acid and its salts and esters	0
ex 29.35 Q	5-Bromopyrimidine	0
ex 29.35 Q	Minoxidil (INN)	0
ex 29.35 Q	Triazolam (INN)	0
ex 29.35 Q	Diazoxide (INN)	0
ex 29.35 Q	Captopril (INN)	0
ex 29.35 Q	Flunixin meglumine (INN ^M)	0
ex 29.35 Q	Tryptophan	0
ex 29.35 Q	Alprazolam (INN)	4,5
ex 29.35 Q	Lasalocid sodium (INN ^M)	0
ex 29.35 Q	1-Hydroxy-4-[1-(4-hydroxy-3-methoxycarbonyl-1-naphthyl)-3-oxo-1 <i>H</i> ,3 <i>H</i> -benzo[<i>de</i>]isochromen-1-yl]-6-octadecyloxy-2-naphthoic acid	0
ex 29.35 Q	Isonicotinonitrile	0
ex 29.35 Q	3,6-Dichloropyridine-2-carboxylic acid	3

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.35 Q	2-Hydroxyethylammonium-3,6-dichloropyridine-2-carboxylate	3
ex 29.35 Q	Bis(2-hydroxyethyl) (9,10-dihydro-10-oxo-9-oxo-10 λ^5 -phospha-10-phenanthryl-methyl) succinate	0
ex 29.35 Q	13,14,15,16-Tetranorlabdano-12,8 <i>alpha</i> -lactone	0
ex 29.35 Q	5-Nitrofurfurylidene di(acetate)	0
ex 29.35 Q	Tetrahydrofuran, containing not more than 40 mg per litre in total of tetrahydro-2-methylfuran and tetrahydro-3-methylfuran for the manufacture of <i>alpha</i> -4-hydroxybutyl- <i>omega</i> -hydroxypoly (oxytetramethylene) (a)	0
ex 29.35 Q	Estazolam (INN)	0
ex 29.35 Q	Timepidium bromide (INN)	0
ex 29.35 Q	Adenosine phosphate (INN)	0
ex 29.35 Q	3-(1-Ethyl-1-methylpropyl)isoxazol-5-ylamine	0
ex 29.35 Q	4,4' -Bis(hydroximinomethyl)-1,1' -(oxydimethylene)-dipyridinium dichloride	0
ex 29.35 Q	(RS)-1-[2-(4-Chlorobenzhydryloxy)ethyl] piperidine and its salts	0
ex 29.35 Q	4-(2-Aminoethylthiomethyl)-1,3-thiazol-ylmethyl-dimethylamine	0
ex 29.35 Q and ex 30.03 A II b)	Butorphanol (INN) and its salts	0
ex 29.35 Q and ex 30.03 A II b)	Buspirone hydrochloride (INN)	0
ex 29.35 Q and ex 30.03 A II b)	Encainide hydrochloride (INN)	0
ex 29.35 Q and ex 30.03 A II b)	Tegafur (INN)	0
ex 29.36	3-[1-(7-Hexadecane-1-sulphonamidoindol-3-yl)-3-oxo-1 <i>H</i> ,3 <i>H</i> -benz-[de]isochromen-1-yl)-indole-7-carboxylic acid	0
ex 29.36	Quinethazone (INN)	0
ex 29.36	Sulfaguanidine (INN)	0
ex 29.36	Sulfathiazole (INN)	0
ex 29.36	4-Chloro-5-sulphamoylanthranil- <i>o</i> -toluidide	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.37	(2,3-Dihydro-3-oxobenz[d]isothiazol-2-yl)-N-5-methylisoxazol-3-ylacetamide S,S-dioxide	0
ex 29.38 A	Nicotinic acid (INN)	0
ex 29.38 B II	Dexpanthenol (INN)	0
ex 29.38 B III	Folic acid (INN)	0
ex 29.38 B V	Nicotinamide (INN)	0
ex 29.39 C I	Serum gonadotrophin (INN)	0
ex 29.39 D II	Betamethasone 17,21-dipropionate (INN)	0
ex 29.39 D II	Diflorasone di(acetate) (INN)	0
ex 29.39 D II	Alclometasone 17,21-dipropionate (INN)	0
ex 29.39 E	Calcitonin (INN), salmon-type and its salts	0
ex 29.39 E	Prasterone (INN)	0
ex 29.39 E	Calcitonin (INN), porcine	0
29.42 C I	Caffeine and its salts	4,1
ex 29.42 C VII	Vindesine sulphate (INN)	0
ex 29.43 B	Ribose	0
ex 29.43 B	Sucralfate (INN)	0
ex 29.43 B	Sucrose benzoate, having a saponification equivalent of not more than 175	0
ex 29.44 A	Epicillin (INN)	0
ex 29.44 A	Piperacillin (INN)	0
ex 29.44 A and ex 30.03 A II a) 1	Piperacillin sodium (INN)	0
ex 29.44 C	Amphotericin B (INN)	0
ex 29.44 C	Minocycline (INN) and its salts	0
ex 29.44 C	Clindamycin (INN) and its salts and esters	0

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.44 C	Spectinomycin dihydrochloride (INN), pentahydrate	0
ex 29.44 C	Nystatin (INN)	0
ex 29.44 C	Sisomicin sulphate (INN)	0
ex 29.44 C	Spectinomycin sulphate (INN)	0
ex 29.44 C	Tobramycin (INN) and its salts	0
ex 29.44 C	Lincomycin (INN) and its salts and esters, for the manufacture of products falling within heading No 30.03 (a)	0
ex 29.44 C	Monensin (INN) and its salts	0
ex 29.44 C	Cefaclor (INN) and its hydrates, salts and esters	0
ex 29.44 C	Netilmicin sulphate (INN)	0
ex 29.44 C	Dibekacin sulphate (INN)	0
ex 29.44 C	Cefoxitin sodium (INN)	0
ex 29.44 C	Cefradine (INN)	0
ex 29.44 C	Cefazolin (INN) and its salts	0
ex 29.44 C	Latamoxef (INN) and its salts and esters	0
ex 29.44 C	Josamycin (INN)	0
ex 29.44 C	Josamycin propionate (INN)	0
ex 29.44 C	Ribostamycin sulphate (INN)	0
ex 29.44 C	Fumagillin dicyclohexylammonium (INN)	0
ex 29.44 C	Ceftazole (INN)	0
ex 29.44 C	Aztreonam (INN)	0
ex 29.44 C	Imipenem (INN)	0
ex 29.44 C	Cefotetan (INN)	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 29.44 C	Ceftizoxime sodium (INN ^M)	0
ex 29.44 C	Midecamycin (INN) and its acetates	0
ex 29.44 C	Neomycin sulphate (INN ^M)	0
ex 29.44 C and ex 30.03 A II b)	Amikacin (INN) and its salts	0
ex 29.44 C and ex 30.03 A II b)	Mitomycin (INN)	0
ex 29.44 C and ex 30.03 A II b)	Bleomycin sulphate (INN ^M)	0
ex 29.44 C and ex 30.03 A II b)	Aclarubicine hydrochloride (INN ^M)	0
ex 29.45	Potassium <i>tert</i> -butoxide	0
ex 30.02 A	Tetanus immunoglobulin	0
ex 30.02 A	Anti-tetanus immunoplasma	0
ex 30.02 A	Whooping-cough immunoplasma	0
ex 30.02 A	Rabies immunoplasma	0
ex 30.03 A II b)	Mixture of oestrogens of equine origin, in powder form	0
ex 30.03 A II b)	Mixture of cefradine (INN) and arginine (INN)	0
ex 30.03 A II b) and B II b)	Human albumin, whether or not in solution	0
ex 30.03 A II b) and B II b)	Preserved serum derived from human blood	0
ex 30.03 A II b) and B II b)	Anti-haemophilic globulin and anti-Rh ₀ (D)-globulin derived from human blood	0
ex 30.03 A II b) and B II b)	Gamma-globulin, in solution, derived from human blood	0
ex 30.03 B II b)	Lyophilized gamma-globulin derived from human blood	0
ex 30.03 B II b)	Purified collagen dispersed in a phosphate physiological saline solution whether or not containing lidocaine (INN)	5

CCT heading No	Description	Rate of autonomous duty (%)
32.01 A I	Tanning extracts of wattle (mimosa)	0
ex 32.01 A IV	Tanning extracts derived from gambier and myrobolan fruits	0
ex 32.01 A IV	Tanning extracts of eucalyptus	3,2
ex 32.08 D	Glass, in the form of flakes, of a length not less than 0,1 mm and not more than 3,5 mm, of a thickness not less than two micrometres and not more than five micrometres	0
ex 32.08 D	Glass in the form of powder or granules, with a silicon dioxide content of not less than 99 % by weight	0
ex 34.02	<i>alpha</i> -Methyl- <i>omega</i> -hydroxypoly(oxypropylene), having an average molecular weight of between 240 and 260	0
ex 34.02	Mixture of docusate sodium (INN) and sodium benzoate	0
ex 35.07	Bromelains (INN)	0
ex 35.07	Mixture of streptokinase (INN) and streptodornase (INN)	0
ex 35.07	Pyruvate: oxygen oxidoreductase	0
ex 35.07	Lipoprotein lipase	0
ex 35.07	Serrapeptase (INN)	0
ex 37.02 B	Colour negative film, of a width not less than 75 mm and not more than 105 mm and of a length of 100 m or more, for use in the manufacture of instant picture film packs (a)	0
ex 38.03 B	Acid activated montmorillonite which, when examined by X-ray powder diffraction, shows four principal lines corresponding to crystal interplane spacing (d values) of 0,44, 0,40, 0,33 and 0,25 nm the line corresponding to 0,40 nm being the most intense, for the manufacture of self-copy paper (a)	0
38.07 B	Spirits of sulphate turpentine; crude dipentene	0
38.07 C	Spirits of wood turpentine; terpenic solvents produced by the distillation or other treatment of coniferous woods; sulphite turpentine; pine oil (excluding 'pine oils' not rich in terpineol)	1,7
ex 38.08 C	Hydroabietyl alcohol	0
ex 38.19 G	Catalysts, in the form of spherical grains with a diameter of not less than 1,4 mm and not more than 1,8 mm, consisting of boron trifluoride on an aluminium oxide support	0
ex 38.19 G	Catalysts, in the form of rodlets having a length of not more than 5,0 mm and a diameter of not more than 3,6 mm, consisting of copper oxide and dichromium trioxide	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 38.19 G	Catalysts, consisting of chromium trioxide or dichromium trioxide fixed on a silicon dioxide support with a pore volume, as determined by the nitrogen absorption method, of not less than 2 cm ³ /g	0
ex 38.19 G	Catalysts, in the form of rodlets having a length of not less than 3 mm and not more than 6 mm and a diameter of not more than 3,8 mm, consisting of not less than 18 % and not more than 21 % by weight of dichromium trioxide and not less than 78 % and not more than 81 % by weight of aluminium oxide	0
ex 38.19 G	Catalysts, in the form of granules, consisting of a mixture of oxides on a carrier of aluminium oxide and containing, by weight: — not less than 12 % and not more than 20 % of nickel — not less than 5 % and not more than 10 % of copper — not less than 0,5 % and not more than 1,5 % of manganese The pore volume is not less than 0,25 cm ³ /g and not more than 0,95 cm ³ /g and the apparent specific gravity is not less than 0,5 and not more than 1,25	0
ex 38.19 G	Catalysts, in the form of grains, of which not less than 90 % by weight have a particle size of less than 10 micrometres, consisting of a mixture of oxides on a carrier of magnesium silicate and containing, by weight: — not less than 20 % and not more than 35 % of copper — not less than 2 % and not more than 3 % of bismuth The catalyst has an apparent specific gravity of not less than 0,2 and not more than 1,0	0
ex 38.19 G	Catalysts, in the form of granules having a diameter of not more than 1,4 mm, consisting of cobalt oxide on a silicon dioxide support	0
ex 38.19 G	Catalysts, in powder form, consisting of a mixture of titanium trichloride and aluminium chloride, containing not less than 20 % and not more than 30 % by weight of titanium and not less than 55 % and not more than 72 % by weight of chlorine	0
ex 38.19 G	Catalysts, in the form of granules or rings having a diameter of not less than 3 mm and not more than 10 mm, consisting of silver supported on aluminium oxide, the silver content being not less than 10 % and not more than 20 % by weight	0
ex 38.19 G	Catalysts consisting of ethyltriphenylphosphonium acetate, dissolved in methanol	0
ex 38.19 G	Catalysts, consisting of copper chloride, supported on aluminium oxide, for the preparation of dichloroethane from ethylene, hydrochloric acid and oxygen, by the fixed bed process (a)	0
ex 38.19 G	Catalysts, in the form of pellets, consisting of mixed vanadium and phosphorus oxides, containing not more than 0,5 % by weight of one of the following elements: lithium, potassium, sodium, cadmium or zinc, for use in the manufacture of maleic anhydride from butane (a)	0
ex 38.19 X	Calcined bauxite (refractory grade)	0
ex 38.19 X	Diosgenin crude	0
ex 38.19 X	4-(6-Fluoro-2-methylinden-3-ylmethyl)phenyl methyl sulphide dissolved in toluene	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 38.19 X	Mixtures of x-butyl-4,4'-isopropylidenediphenol and x,x'dibutyl-4,4'-isopropylidene-diphenol	0
ex 38.19 X	Mixture of nitromethane and 1,2-epoxybutane	0
ex 38.19 X	Residues of manufacture containing not less than 40 % by weight of 11- <i>beta</i> , 17,20,21-tetrahydroxy-6-methylpregna-1,4-dien-3-one-21-acetate	0
ex 38.19 X	Intermediate products from the manufacture of monensin salts	0
ex 38.19 X	Tetramethylammonium hydroxide dissolved in methanol	0
ex 38.19 X	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Streptomyces tenebrarius</i> , whether or not dried	0
ex 38.19 X	Products obtained by the N-ethylation of sisomicin (INN)	0
ex 38.19 X	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Micromonospora purpurea</i> , whether or not dried	0
ex 38.19 X	Cholic acid and 3- <i>alpha</i> , 12- <i>alpha</i> , dihydroxy-5- <i>beta</i> , cholan-24-oic acid (deoxycholic-acid), crude	0
ex 38.19 X	Crude bile acids	0
ex 38.19 X	Colloidal di-antimony pentaoxide	0
ex 38.19 X	Tetrakis(2-chloroethyl) ethylene bis(phosphate)	5
ex 38.19 X	Grains, consisting of a mixture of dialuminium trioxide and zirconium dioxide, containing by weight not less than 70 % and not more than 78 % dialuminium trioxide and not less than 19 % and not more than 26 % zirconium dioxide	5,2
ex 38.19 X	Grains, consisting of a mixture of dialuminium trioxide and zirconium dioxide, containing by weight not less than 54 % and not more than 62 % dialuminium trioxide and not less than 36 % and not more than 44 % zirconium dioxide	5,2
ex 38.19 X	Magnesium bromide 2-oxoperhydroazepin-1-ide dissolved in <i>epsilon</i> -caprolactam to a concentration of not less than 20 % and not more than 25 % by weight	0
ex 38.19 X	Reaction products of dibutyl dihydrogendiphosphate and 1,2-epoxypropane for use in the production of non-rigid polyurethane (a)	0
ex 38.19 X	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Micromonospora inyoensis</i> , whether or not dried	0
ex 38.19 X	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Streptomyces kasugaensis</i> , whether or not dried	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 38.19 X	Film consisting of the oxides of barium, calcium and either titanium or zirconium, mixed with binding materials	0
ex 38.19 X	Mixture of amines derived from dimerized fatty acids with an average molecular weight of between 520 and 550	0
ex 38.19 X	Mixture obtained by fermentation containing not less than 5 % by weight peptides having the structure of the A chain of human insulin in the form of a salt of the S-sulphonate derivative	0
ex 38.19 X	Mixture obtained by fermentation containing not less than 5 % by weight peptides having the structure of the B chain of human insulin in the form of a salt of the S-sulphonate derivative	0
ex 38.19 X	Crude lithium hypochlorite	0
ex 38.19 X	Reaction mixture containing benzyl 3-isobutyryloxy-1-isopropyl, 2,2-dimethylpropyl phthalate and benzyl 3-isobutyryloxy-2,2, 4-trimethylpentyl phthalate	0
ex 38.19 X	Mixture of 2-(perfluoroalkyl)ethanethiols containing C ₆ to C ₁₄ perfluoroalkyl chains	0
ex 38.19 X	Lyophilized extract of the blood cells of the crab <i>Limulus polyphemus</i> ('Limulus amoebocyte lysate')	0
ex 38.19 X	A mixture of 5-ethyl-2-methyl-2-oxo-1,3,2λ ⁵ -dioxaphosphoran-5-ylmethyl methyl methylphosphonate and bis(5-ethyl-2-methyl-2-oxo-1,3,2λ ⁵ -dioxaphosphoran-5-ylmethyl) methylphosphonate	0
ex 38.19 X	Butylethylmagnesium dissolved in organic solvents to a concentration of not less than 19 % but not more than 30 % by weight	0
ex 38.19 X	Mixed oxides of barium, bismuth, lead, titanium and zinc in powder form, having a barium content of not less than 5 % and a titanium content of not less than 15 % by weight, for use as dielectric materials during the manufacture of multilayer ceramic capacitors (a)	0
ex 38.19 X	Lithium niobate wafers, undoped	0
ex 38.19 X	4-(2-Aminoethylthiomethyl)-1,3-thiazol-2-ylmethyldimethylamine, dissolved in toluene	0
ex 38.19 X	Tetra-Aluminium nonamagnesium dicarbonate hexacosahydroxide heptahydrate coated with a surface active agent	0
ex 39.01 A	Colestipol hydrochloride (INNM)	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.01 C I a)	Polycondensation products of phenol and formaldehyde in the form of hollow spheres with a diameter of less than 150 micrometres	0
ex 39.01 C III a)	Reflecting polyester sheeting embossed in a regular pyramidal pattern	0
ex 39.01 C III a)	Reflecting polyester sheeting in which microspheres are embedded	0
ex 39.01 C III a)	Transparent film consisting of polyester coated with a layer of indium and silver	0
ex 39.01 C III a)	Polyester film, having a thickness of not less than 74 micrometres and not more than 76 micrometres, for use in the manufacture of flexible magnetic discs (floppy discs) (a)	0
ex 39.01 C III a)	Reflecting laminated sheeting, metallized, consisting of one sheet of polyester and at least another sheet of polyester or other plastic material and coated on one side with an adhesive, whether or not protected by a release sheet	0
ex 39.01 C III a)	Iridescent film of polyester and poly(methyl methacrylate)	0
ex 39.01 C III b)	Polyester of a mixture of isophthalic acid and terephthalic acid with 4,4'-isopropylidenediphenol	0
ex 39.01 C III b)	Waste and scrap from polyester film coated with a tungsten compound or with rare-earth metal compounds	0
ex 39.01 C III b)	Poly(oxy-1,4-phenylenecarbonyl) in powder form	0
ex 39.01 C III b) and ex 39.03 B II b) 2, B III b) 4 aa) and B IV b) 4 aa)	Waste and scrap of photographic (including cinematographic) and X-ray film	0
ex 39.01 C IV	Poly(iminomethylene-1,3-phenylenemethyleneiminoadipoyl) in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.01 C IV	Film consisting of poly(<i>epsilon</i> -caprolactam) blended with: — either not more than 10 % by weight of polyethylene — or not more than 10 % by weight of a copolymer of ethylene with vinyl acetate	0
ex 39.01 C IV	Poly(<i>epsilon</i> -caprolactam) film having a softening point of not less than 200 °C	0
ex 39.01 C V	Reflecting polyurethane sheeting	0
ex 39.01 C VII	Polyimide sheet and strip	0
ex 39.01 C VII	Poly[oxy(2,6-dibromo-1,4-phenylene)] for use in the manufacture of polyamide (a)	0
ex 39.01 C VII	Poly(oxy-1,4-phenylenesulphonyl-1,4-phenyleneoxy-1,4-phenyleneisopropylidene-1,4-phenylene) in one of the forms mentioned in note 3 (b) to Chapter 39	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.01 C VII	Liquid poly(oxypropylene) with 3-(3-{2-[2-(2-mercaptoethoxy)ethoxy]ethylthio} propoxycarbonylamino)- <i>p</i> -tolylcarbamoxyloxy as the end group	0
ex 39.01 C VII	Poly[oxy-1,4-phenyleneisopropylidene-1,4-phenyleneoxy-(2-hydroxytrimethylene)], with an average molecular weight of more than 26 000, in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.01 C VII	Reaction product of poly(oxylalkylene) polyol with a polycarboxylic acid and epsilon-caprolactam	0
ex 39.02 A	Ion-exchange membranes in fluorcoated plastic material, for use in chlor-alkali electrolytic cells (a)	0
ex 39.02 C I a)	Synthetic paper pulp, in the form of moist sheets made from unconnected finely branched, polyethylene fibrils, whether or not blended with cellulose fibres in a quantity not exceeding 15 %, containing polyvinyl alcohol dissolved in water as the moistening agent	0
ex 39.02 C I a)	Synthetic paper pulp, in the form of moist sheets made from unconnected finely branched fibrils of a mixture of polyethylene and a polyethylene copolymer, whether or not blended with cellulose fibres in a quantity not exceeding 15 %, containing polyvinyl alcohol dissolved in water as the moistening agent	0
ex 39.02 C II	Microporous polytetrafluoroethylene film coated on one side with a polymer permeable to water vapour not less than 30 cm in width and weighing not more than 50 g/m ²	0
ex 39.02 C II	Microporous polytetrafluoroethylene film of a width of not less than 30 cm and weighing not more than 22,4 g/m ²	0
ex 39.02 C II	Poly(1-chlorotrifluoroethylene) film	0
ex 39.02 C IV	Synthetic paper pulp, in the form of moist sheets made from unconnected finely branched polypropylene fibrils, whether or not blended with cellulose fibres in a quantity not exceeding 15 %, containing polyvinyl alcohol dissolved in water as the moistening agent	0
ex 39.02 C VI a)	Copolymer, entirely of maleic anhydride and styrene, whether or not containing a styrene-butadiene block copolymer in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C VI a) and b)	Copolymers, solely of allyl alcohol with styrene, which have an acetyl value of not less than 175	0
ex 39.02 C VII b)	Polyvinyl chloride sheeting, of a thickness of less than 1 mm, coated with an adhesive in which are embedded hollow glass balls having a diameter of not more than 100 micrometres	0
ex 39.02 C VII b)	Reflecting polyvinyl chloride sheeting, wholly embossed on one side in a regular pyramidal pattern	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.02 C VIII	Copolymers of vinylidene chloride with vinyl chloride, containing not less than 79,5 % by weight of vinylidene chloride, in one of the forms mentioned in note 3 (a) and (b) to Chapter 39, for the manufacture of fibres, monofil or strip (a)	0
ex 39.02 C XI	Poly(vinyl formal), in one of the forms mentioned in note 3 (b) to Chapter 39, having a molecular weight not less than 10 000 and not more than 40 000 and containing, by weight: — not less than 9,5 % and not more than 13 % of the acetyl groups, expressed as vinyl acetate — not less than 5 % and not more than 6,5 % of the hydroxy groups, expressed as vinyl alcohol	0
ex 39.02 C XI	Films of a thickness of not more than 1 mm, entirely of polyvinyl-alcohol, containing not more than 2 % by weight of unhydrolyzed acetate groups expressed as vinyl acetate and not less than 5 % and not more than 15 % by weight of glycerol as a plasticizer	0
ex 39.02 C XI	Polyvinyl alcohol film coated on both sides having a total thickness of less than 1 mm and with an extension at break (longitudinal or transversal) of not less than 65 %	0
ex 39.02 C XI	Polyvinyl alcohol film containing not less than 99 % by weight of polyvinyl alcohol, uncoated, with a thickness of not more than 1 mm	0
ex 39.02 C XII	Copolymers of 2-di-isopropylaminoethyl methacrylate and decyl methacrylate dissolved in N,N-dimethylacetamide, with a copolymer content of not less than 55 % by weight	0
ex 39.02 C XII	Copolymerization products of acrylic and methacrylic esters, in the form of film with a thickness not exceeding 150 micrometres	0
ex 39.02 C XII	Copolymer of acrylic acid and 2-ethylhexyl acrylate, containing not less than 10 % and not more than 11 % by weight of 2-ethylhexyl acrylate	0
ex 39.02 C XII	Poly[N-(3-hydroxyimino-1,1-dimethylbutyl)acrylamide]	0
ex 39.02 C XII	Reflecting polyacrylic sheeting in which microspheres are embedded	0
ex 39.02 C XIV a)	Copolymers of vinyl chloride with vinyl acetate and vinyl alcohol, containing by weight not less than 89 % and not more than 92 % of vinyl chloride, not less than 2 % and not more than 6 % of vinyl acetate and not less than 4 % and not more than 8 % of vinyl alcohol, in one of the forms mentioned in note 3 (a) and (b) to Chapter 39	0
ex 39.02 C XIV a)	Poly(1-ethylethylene) (Polybutene-1) in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C XIV a)	Alternating copolymer of ethylene and maleic anhydride, for use as a thickener in textile pigment printing pastes (a)	0
ex 39.02 C XIV a)	Copolymer of acrylonitrile and methylacrylate modified with polybutadieneacrylonitrile (NBR)	0
ex 39.02 C XIV a)	Polyvinyl fluoride in one of the forms mentioned in note 3 (b) to Chapter 39	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.02 C XIV a)	Poly(tribromostyrene), containing not less than 66 % and not more than 71 % by weight of bromine, in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C XIV a)	Synthetic paper pulp, in the form of moist sheets made from unconnected finely branched fibrils of polypropylene modified by an organic acid, whether or not blended with cellulose fibres in a quantity not exceeding 15 %, containing polyvinyl alcohol dissolved in water as the moistening agent	0
ex 39.02 C XIV a)	Polymerization products of acrylic acid with small quantities of a polyunsaturated monomer for use as a thickener in textile pigment printing pastes or in the manufacture of products falling within heading No 30.03 (a)	0
ex 39.02 C XIV a)	Terpolymer of ethylene, methyl acrylate and a monomer containing a non-terminal carboxy group as a substituent, whether or not compounded with silica	8
ex 39.02 C XIV a)	Polymerization products of a (polybutadiene)polyol and two lactams N,N'-linked by the bivalent acyl radical of a dicarboxylic acid	0
ex 39.02 C XIV a)	Copolymer of ethylene with chlorotrifluoroethylene, in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C XIV a)	Terpolymer of ethylene with chlorotrifluoroethylene and hexafluoro(2-methylpropene) in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C XIV a)	Copolymer of tetrafluoroethylene and hexafluoropropene compounded with not less than 1 % and not more than 51 % by weight of one of the following: — barium sulphate — dibismuth trioxide — dibismuth carbonate dioxide — tungsten in one of the forms mentioned in note 3 (b) to Chapter 39	0
ex 39.02 C XIV b)	Polyvinyl fluoride sheet	0
ex 39.02 C XIV b)	Reflecting sheeting of an acrylic polymer modified by melamine-formaldehyde	0
ex 39.02 C XIV b)	Copolymer of ethylene with propylene in the form of self-adhesive strip of a width of not less than 18 mm and not more than 27 mm or not less than 58 and not more than 90 cm and of a thickness not exceeding 1 mm; which, after being extended at 23 °C to twice their original length, returns to its original length, with a tolerance of not more than + 15 %, within a period of two minutes	0
ex 39.02 C XIV b)	Film of a thickness of not more than 1 mm of a copolymerization product of vinyl alcohol with ethylene containing no other polymerization products or copolymerization products, with an extension at break (longitudinal or transversal) of not less than 65 %	0
39.03 B V a) 1	Ethylcellulose, not plasticized	4
ex 39.03 B V a) 2	Alkylhydroxyethylcellulose	4

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 39.03 B V a) 2	Hydroxyalkylhydroxyethylcellulose	0
ex 39.06 B I	0-(2-hydroxyethyl)amylopectin hydrolysate	0
ex 39.07 B V d)	Reflecting sheeting or tape, consisting of a facing strip of polyvinyl chloride embossed in a regular pyramidal pattern, heat sealed in parallel lines or a grid pattern to a backing strip of plastic material, or of knitted or woven fabric covered on one side with plastic material	0
ex 39.07 B V d)	Two polyethylene sheets containing multiple slits laid crosswise upon each other and bonded together	0
ex 41.02 C	Leather of East India kip, whole, whether or not the heads and legs have been removed, each weighing more than 4,5 kg net and not more than 8 kg, not further prepared than vegetable tanned, whether or not having undergone further preservative treatment with oil, but obviously unsuitable for immediate use in the manufacture of leather articles	0
41.03 B I	Sheep and lambskin leather, except leather falling within heading No 41.06 or 41.08, other, not further prepared than tanned	0
41.04 B I	Goat and kidskin leather, except leather falling within heading No 41.06 or 41.08, other, not further prepared than tanned	0
41.05 B I	Other kinds of leather, except leather falling within heading No 41.06 or 41.08, other, not further prepared than tanned	0
ex 44.22 B	Used casks and barrels of oak, whether assembled or not; their staves and heads	0
ex 44.28 C	Match splint, manufactured from aspen (<i>Populus tremuloides</i>), for the manufacture of matches not requiring a specific striking surface (so called 'strike-anywhere' matches) (a)	0
ex 44.28 D II	Shingles for roofs and walls, of coniferous wood	0
45.01	Natural cork, unworked, crushed, granulated or ground; waste cork	0
45.02	Natural cork, in blocks, plates, sheets or strips (including cubes or square slabs, cut to size for corks or stoppers)	4
ex 48.07 D	Coloured paper, impregnated with acrylic resin and coated with poly(vinylidene chloride), or coated with acrylic resin, having a thickness of not less than 200 micrometres and not more than 255 micrometres and a weight per square metre of not less than 165 grams and not more than 185 grams	0
ex 48.21 F II	Strips of paper glued to one another to form a honeycomb with a maximum height of 13 cm, impregnated with a copper-based preservative	0
ex 49.11 B	Artists' screen prints (commonly described as serigraphs), signed by the artist and numbered from 1 to 200	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 49.11 B	Microcopies on an opaque base for data banks and libraries (a)	0
ex 51.01 A	Yarn of polytetrafluoroethylene	0
ex 51.01 A	Yarn of polyvinyl alcohol, soluble in water at a temperature of 50 °C, for use in the manufacture of weftless 'felts' for papermaking machines (a)	0
ex 51.01 A	Yarn of a copolymer of glycolic acid and lactic acid for the manufacture of surgical sutures (a)	0
ex 51.01 A	Yarn wholly of polyglycollic acid	0
ex 51.01 A	Yarn of poly(1,4-dioxanone)	0
ex 51.01 A	Non-textured filament yarn of poly(vinyl alcohol), for the manufacture of sleeves for printing rollers (a)	0
ex 51.01 A	Yarn of synthetic textile fibres exclusively of aromatic polyamides obtained by the polycondensation of <i>m</i> -phenylenediamine and isophthalic acid	0
ex 51.01 A	Polyamide yarn, not textured, untwisted or with not more than 22 turns per metre, of crimpable bicomponent filaments consisting of poly(hexamethylene adipamide) and a copolyamide for the manufacture of knee-length stockings falling within subheading 60.03 B I, women's stockings falling within subheading 60.03 B II a) or panty hose (tights) falling within subheading 60.04 B III a) 1 (a)	0
ex 51.02 A I	Monofil of poly(1,4-dioxanone)	0
ex 51.02 A I	Monofil of a copolymer of 1,3-dioxan-2-one with 1,4-dioxan-2,5-dione for the manufacture of surgical sutures (a)	0
ex 51.02 A II	Polyimide strip	0
ex 51.02 A II	Strip of polytetrafluoroethylene, with an extension at break not exceeding 25 %	0
ex 51.04 A IV	Woven fabrics of polyvinyl alcohol fibres, for machine embroidery	0
ex 51.04 A IV or ex 59.08	Woven poly(tetrafluoroethylene) fibre fabric coated on one side with a copolymer of tetrafluoroethylene and trifluoroethylene having perfluorinated alkoxy side chains ending in carboxylic acid or sulphonic acid groups in the potassium or sodium salt form, whether or not coated on the same side with a metallic inorganic compound	0
ex 54.03 B I a)	Unbleached linen yarn (excluding yarn of flax tow), measuring per kilogram 30 000 m or less, for the manufacture of multiple or cabled yarns of the footwear industry or for whipping cable (a)	1,8
ex 56.01 A	Textile fibres of polytetrafluoroethylene	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 56.01 A	Textile fibres exclusively of aromatic polyamides obtained by the polycondensation of <i>m</i> -phenylenediamine and isophthalic acid, for uses other than the manufacture of articles falling within Chapters 60, 61, 64 and 65 or of materials used in the manufacture of such articles (a)	0
ex 56.01 A	Textile fibres containing not less than 85 % by weight of fibres of aromatic polyamides obtained by the polycondensation of <i>m</i> -phenylenediamine and isophthalic acid and not less than 1 % and not more than 15 % by weight of fibres of poly (<i>p</i> -phenylene terephthalamide)	5
ex 56.01 A	Fibres wholly of poly(thio-1,4-phenylene)	0
ex 56.01 A and ex 59.01 B I	Polyvinyl alcohol fibres, whether or not acetalized	0
ex 56.01 B	Fibres entirely of Modal (ISO)	0
ex 59.03 B	Bonded fibre fabrics and similar bonded yarn fabrics of aromatic polyamide man-made fibres obtained by polycondensation of <i>m</i> -phenylenediamine and isophthalic acid, whether or not impregnated or coated, in the piece or cut into rectangles	0
ex 59.03 B	Bonded fibre fabrics with a thickness of not more than 300 micrometres of spun-bonded polyethylene fibres, with a weight not exceeding 115 g/m ² , whether or not impregnated or coated, in the piece or cut into rectangles	0
ex 59.03 B	Bonded fibre fabrics of polypropylene consisting of a meltblown central layer, laminated on each side with spun-bonded fibres, with a thickness of not more than 550 micrometres and a weight not exceeding 80 g/m ² , in the piece or simply cut into rectangular shape, not impregnated or coated	0
ex 59.03 B	Spun-bonded fibre fabric of continuous polyester filaments bonded together with polyacrylates, pressed and embossed with a weave pattern, whether or not impregnated or coated, in the piece or cut into rectangles	0
ex 59.04	Coir yarn, for the manufacture of carpets, carpeting and rugs, mats and the like (a)	0
ex 59.08	Knitted or woven fabric, coated or covered on one side with artificial plastic material in which are embedded microspheres	0
ex 59.12	Textile fabrics coated with adhesive in which are embedded microspheres, the diameter of which is not more than 75 micrometers, and weighing not more than 550 g/m ²	0
ex 59.17 D	Yarn and strip of impregnated polytetrafluoroethylene, whether or not oiled or graphited	0
62.03 A I	Sacks and bags, of a kind used for the packing of goods, used, of jute or of other textile bast fibres of heading No 57.03	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
62.03 B I a)	Sacks and bags, of a kind used for the packing of goods, used, of flax or of sisal	0
ex 68.16 B	Microspheres containing more than 90 % by weight of barium and titanium expressed as barium oxide and titanium dioxide with a diameter of less than 100 micrometers and a refractive index of not less than 2,1 and not more than 2,4	0
ex 69.03 C and ex 69.14 B	Yarn of continuous ceramic filaments, each filament of which contains not less than 12 % by weight of diboron trioxide, not more than 26 % by weight of silicon dioxide and not less than 60 % by weight of dialuminium trioxide	0
ex 69.09 B	Catalysts supports consisting of porous cordierite or mullite ceramic pieces of roughly circular, square, rectangular or oval cross-section with parallel sides having an overall volume of not less than 240 ml and not more than 50 000 ml, and having a minimum external dimension of not less than 20 mm and a maximum external dimension of not more than 1 800 mm, having not less than one continuous channel per 100 mm ² running parallel to the main axis of symmetry, the total channel cross-section area being not less than 10 % and not more than 80 % of the whole cross-section area	0
ex 69.09 B	Plates made of dialuminium trioxide and titanium carbide with dimensions of not more than 48 × 48 mm, for the manufacture of magnetic heads (a)	0
ex 70.11	Glass envelopes, for monochrome cathode ray tubes, having the following dimensions: — diagonal face not less than 3,8 cm and not exceeding 51 cm, and — nominal neck diameter of 13 mm, 20 mm, 29 mm or 37 mm	0
ex 70.20 A	Non-textile glass fibres having a diameter of less than four micrometres	0
ex 70.20 A	Webs, felts, thin sheets and similar products of non-textile glass fibres, of a weight per square metre of not more than 120 g and a fibre diameter, excluding any coating, of not more than 7 micrometres, for the manufacture of filtration products (a)	0
ex 70.20 B	Yarns of 33 tex ± 7,5 %, or a multiple thereof obtained from continuous spun glass filaments having a diameter of not less than 2,5 micrometres and not more than 5,1 micrometres, other than those treated so as to improve their adhesion to elastomers	0
ex 70.20 B	Yarns obtained from continuous spun glass filaments having a diameter of not less than 12,5 micrometres and not more than 13,5 micrometres treated with resorcino-formaldehyde, of not less than 340 tex and not more than 680 tex	7
ex 70.20 B	Yarns of 22 tex spun from continuous glass filaments having a diameter of not less than 4,7 and not more than 5,5 micrometres	0
ex 70.20 B	Yarns of 33, 34 or 51 tex ± 7,5 %, or a multiple thereof, spun from continuous glass filaments having a diameter of not less than 5,8 micrometres and not more than 7,1 micrometres	0
ex 74.05 B	Sheets and plates of polytetrafluoroethylene, with aluminium oxide or titanium dioxide as a filler or reinforced with glass-fibre fabric, laminated on both sides with copper foil	0
ex 75.04 A	Tubes of nickel, not alloyed, of a purity not less than 99 % by weight, not deviating from straightness lengthwise by more than 1 mm per 150 cm of length, and with an outside diameter either:	

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 75.04 A (cont'd)	— not less than 213,36 mm and not more than 214 mm or — not less than 209,95 mm and not more than 210,59 mm or — not less than 168,28 mm and not more than 168,78 mm	0
76.01 B I b)	Waste of aluminium, other (including factory rejects)	0
ex 76.03	Aluminium alloy rectangular strip in coils, not lacquered, varnished, painted or plastic-coated, having a width of not less than 75 and not more than 230 mm and a thickness of not less than 2,9 and not more than 6,5 mm, containing by weight: — not less than 18 % and not more than 23 % of tin — not less than 0,7 % and not more than 1,5 % of copper — other metals where present each having a concentration lower than that of the copper	0
ex 77.02	Ground and polished magnesium sheets whose dimensions do not exceed 1 500 × 2 000 mm, coated on one side with epoxy resin, insensitive to light	0
ex 81.03 B	Wire of unalloyed tantalum, of a diameter not less than 0,2 mm and not more than 0,5 mm, for the manufacture of capacitors (a)	0
ex 81.04 G I	Electrolytic manganese of a purity of at least 99,7 % by weight, for the chemical industry (a)	0
ex 81.04 G I	Electrolytic manganese of a purity of at least 99,7 % by weight, for the production of non-ferrous alloys (a)	0
ex 81.04 K I	Waste and scrap titanium	0
ex 81.04 K I	Titanium sponge	0
ex 84.18 C II b)	Components of separators for the separation of gases from gas mixtures, consisting of a bundle of permeable hollow fibres passing through a block of plastic material at one end and sealed at the other end — the whole being enclosed within a metal container, whether or not perforated, of an overall length of not less than 300 mm and not more than 3 700 mm and a diameter of not more than 350 mm	0
ex 84.18 C II b)	Parts of equipment for the purification of water by reverse osmosis, consisting essentially of plastic-based membranes, supported internally by textile materials which are wound round a perforated tube of plastic material and housed in a plastic cylinder	0
ex 84.18 C I b)	Parts of equipment, for the purification of water by reverse osmosis, consisting of a bundle of hollow fibres of artificial plastic material with permeable walls, embedded in a block of artificial plastic material at one end and passing through a block of artificial plastic material at the other end, the whole being enclosed in an artificial plastic cylinder	0
ex 84.31 A	Suction roll shells, not drilled, being alloy steel tubes with a length of not less than 5 207 mm and an outside diameter of not less than 754 mm, for use in machinery for making paper or paperboard (a)	0
ex 84.51 A	Typewriters with Braille characters	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.

CCT heading No	Description	Rate of autonomous duty (%)
ex 84.51 A	Electronic pocket communicators for handicapped persons which, by means of push buttons and printing thermic head, print and issue text on tape	0
ex 85.21 E	Tungsten elements coated with insulating material, grids and cathodes for use in the manufacture of electron guns for monochrome cathode-ray tubes (a)	0
ex 85.22 C II	Electromagnetic displays consisting of seven electromagnetic coils, which by means of the residual magnetism in the stators provide indefinite memory, and seven pivoting light-reflecting segments each of which is attached to a bar magnet. The display is contained in a housing the exterior dimensions of which do not exceed 28 × 36 × 50 mm	0
ex 85.22 C II	Portable machines for reading and writing Braille with tactile read-out and magnetic tape cassette recording systems, microphone and speaker, equipped with a standard electro-mechanical Braille typewriter keyboard and an electromechanical Braille read-out unit with 20 characters, all contained in a case whose exterior dimensions do not exceed 24 × 36 × 11 cm	0
ex 90.01 A II	Octagonal Fresnel lens of acrylic resin unmounted, for use in overhead projectors (a)	0
ex 90.01 B	Material consisting of a polarizing film, supported on one or both sides by transparent material	0
ex 90.19 A III	Vascular prostheses of which the largest opening has an internal diameter not exceeding 8 mm	0
ex 90.19 A III	Vascular prostheses incorporating a tubular carrier made of yarns enclosed in animal collagen	0
ex 90.19 A III	Heart valves and parts thereof	0
ex 90.19 B I	Receivers of hearing aids, contained in a housing whose external dimensions excluding connecting points do not exceed 5 × 6 × 8 mm	0
ex 90.19 B II	Reading appliances for the blind, in which a miniature camera using photo-transistors transmits letters onto a scanning board with piezo-electric pencils, and their parts and accessories	0
ex 91.11 C II or ex 91.11 F	Assembly consisting of a printed circuit on which is mounted one quartz oscillator, at least one watch circuit and at least one capacitor, of a thickness not exceeding 5 mm for the manufacture of products falling within Chapter 91 (a)	0
ex 91.11 F	Assembly consisting of a printed circuit on which is mounted a watch circuit, with a thickness not exceeding 5 mm, for the manufacture of products falling within Chapter 91 (a)	0
ex 98.04 A II	Non-fibrous plastic pen-tips with an internal channel	0
ex 98.10 B	Flint wheels, whether or not with guard wheels, for use in the manufacture of non-refillable gas-fuelled pocket lighters (a)	0
ex 98.10 B	Piezo-electric ignition mechanism	0

(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.